ELECTRONIC CIRCUIT ANALYSIS

(AEC004)

B.TECH IV semester ECE

(AUTONOMOUS-R16)

UNIT I
SINGLE STAGE AMPLIFIERS AND FREQUENCY RESPONSE

Classification of Amplifiers

Type of Signal	Based on No.of Stages	Type of Configuration	Classification based on conduction angle	Frequency of Operation
Small Signal	Single Stage	Common Emitter	Class A Amplifier	Direct Current (DC)
Large Signal	Multistage	Common Base	Class B Amplifier	Audio Frequencies (AF)
		Common Collector	Class AB Amplifier	Radio Frequencies (RF)
			VHF, UHF and SHF Class C Amplifier	Frequencies

Different Regions Of Operation

Region of Operation	Emitter Base Junction	Collector Base Junction
Cut off	Reverse biased	Reverse biased
Active	Forward biased	Reverse biased
Saturation	Forward biased	Forward biased

Transistor Voltage specifications For Various Operating Regions

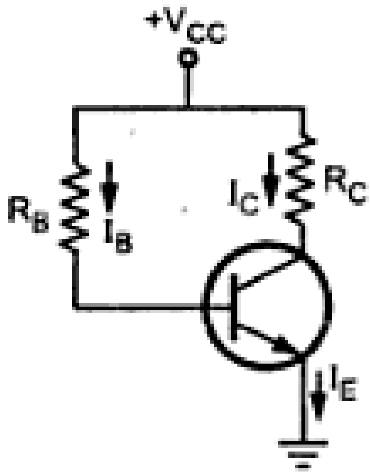
Transistor	$V_{CE\,(sat)}$	$V_{BE\,(sat)}$	$V_{BE\,(active)}$	$V_{BE\,(cut\text{-}in)}$	$V_{BE\,(cut\text{-}off)}$
Si	0.2 V	0.8 V	0.7 V	0.5 V	0 V
Ge	0.1 V	0.3 V	0.2 V	0.1 V	– 0.1 V

Condition forActive & Saturation Regions

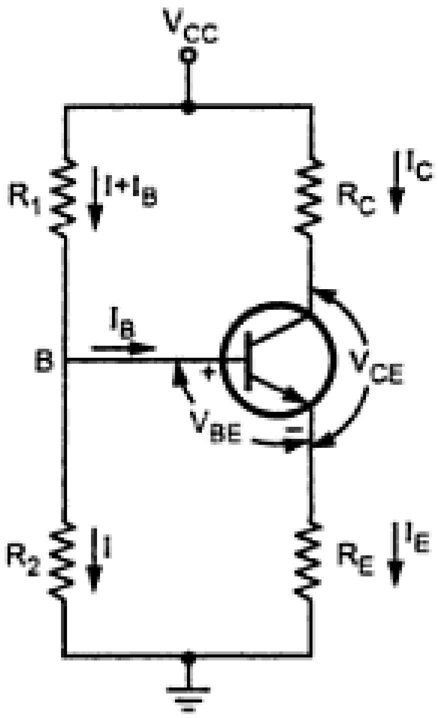
For saturation : $\boxed{I_B > \frac{I_C}{\beta_{dc}}}$

For active region : $\boxed{V_{CE} > V_{CE\,(sat)}}$

Transistor Biasing

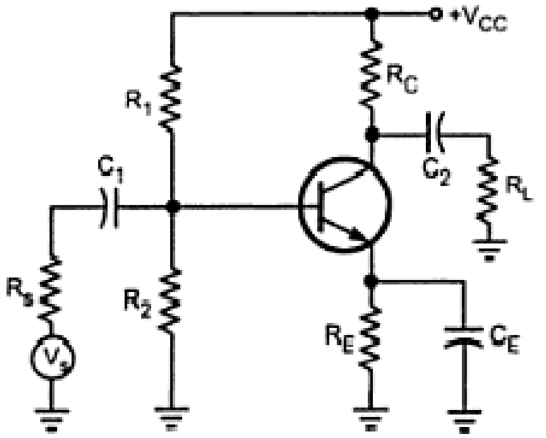


Fixed bias circuit

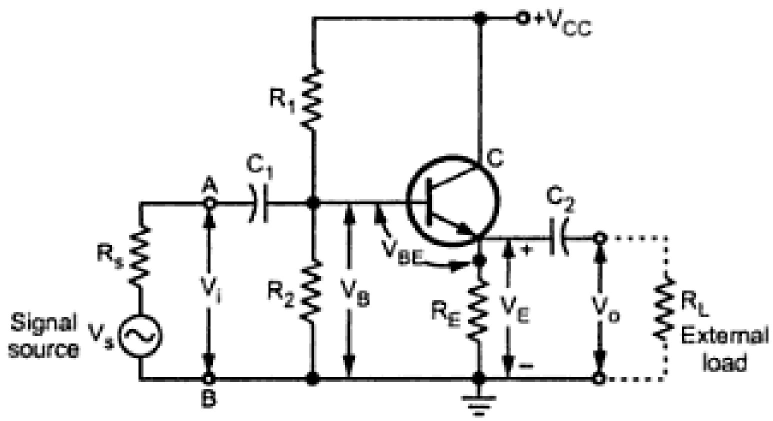


Voltage divider bias circuit

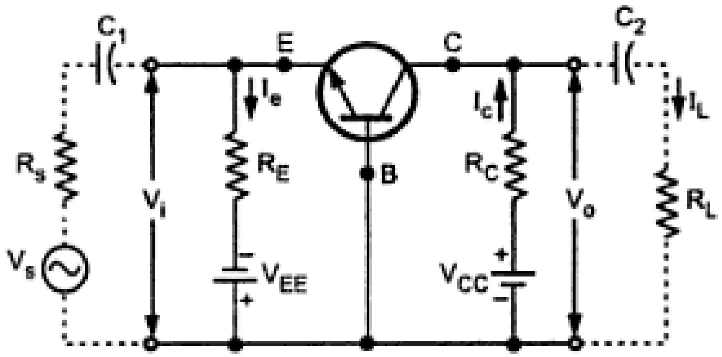
CE, CC, & CB Amplifiers



Practical common emitter amplifier circuit



Common collector circuit



Common base circuit

H-Parameters Representation Of AnAmplifier

$$V_i = h_{11} I_i + h_{12} V_o$$
$$I_o = h_{21} I_i + h_{22} V_o$$

Definitions of h-parameter

The parameters in the above equation are defined as follows :

$h_{11} = \left.\frac{V_i}{I_i}\right|_{V_o=0}$ = Input resistance with output short-circuited, in ohms.

$h_{12} = \left.\frac{V_i}{V_o}\right|_{I_i=0}$ = Fraction of output voltage at input with input open circuited.

This parameter is ratio of similar quantities, hence unitless

$h_{21} = \left.\frac{I_o}{I_i}\right|_{V_o=0}$ = Forward current transfer ratio or current gain with output short circuited.

This parameter is a ratio of similar quantities, hence unitless.

$h_{22} = \left.\frac{I_o}{V_o}\right|_{I_i=0}$ = Output admittance with input open-circuited, in mhos.

a) With output short circuited :

$h_{11} = h_i$: Input resistance

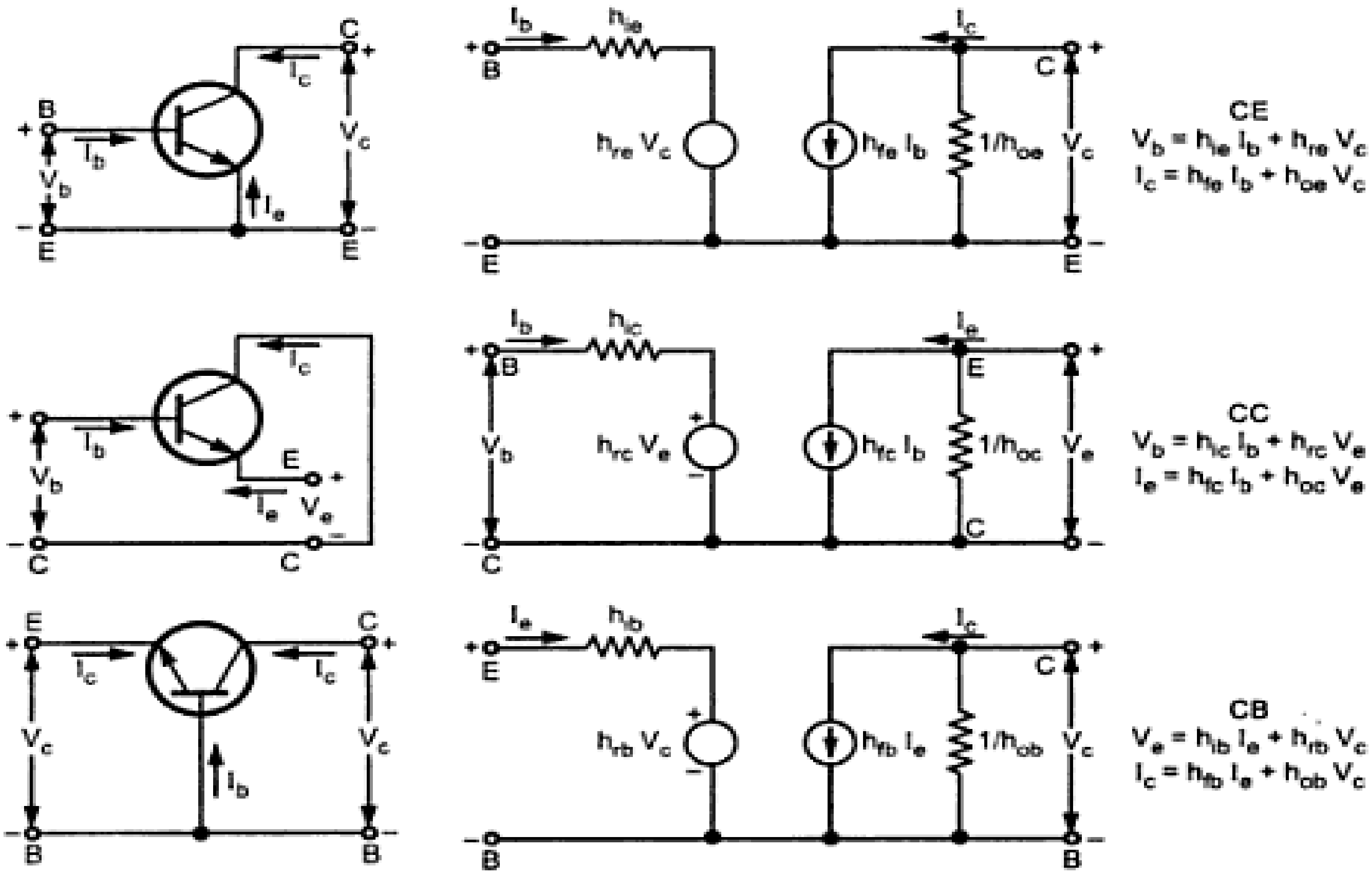
$h_{21} = h_f$: Short circuit current gain

b) With input open circuited :

$h_{12} = h_r$: Reverse voltage transfer ratio

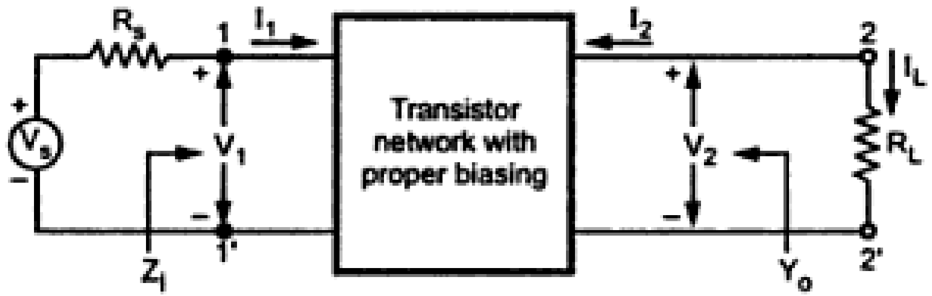
$h_{22} = h_o$: Output admittance

Hybrid model of CE, CC, & CBAmplifiers

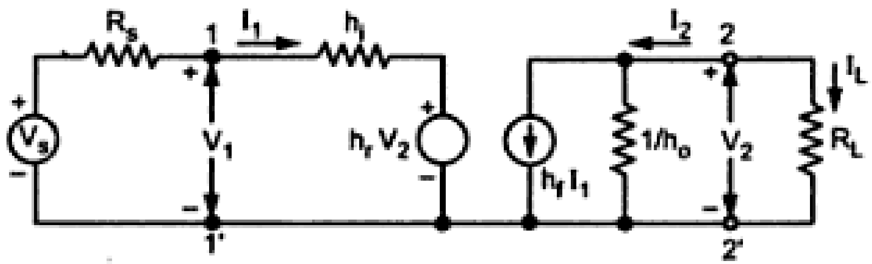


Transistor configurations and their hybrid models

Small Signal Analysis Of A Junction Transistor



Basic transistor amplifier



Transistor amplifier in its h-parameter model

Small signal analysis of transistor amplifier

small-signal analysis of a transistor amplifier

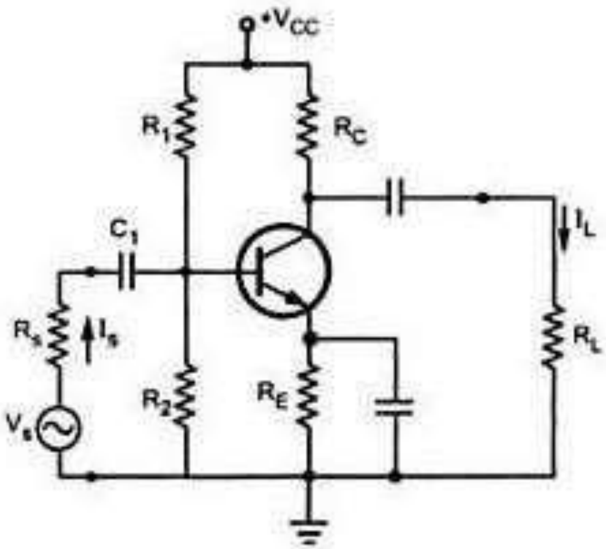
$A_i = -\dfrac{h_f}{1 + h_o R_L}$
$A_{is} = \dfrac{A_i R_s}{Z_i + R_s}$
$Z_i = h_i + h_r A_i R_L = h_i - \dfrac{h_f h_r}{h_o + Y_L}$
$A_v = \dfrac{A_i R_L}{Z_i}$
$A_{vs} = \dfrac{A_v R_i}{Z_i + R_s} = \dfrac{A_i R_L}{Z_i + R_s} = \dfrac{A_{is} R_L}{R_s}$
$Y_o = h_o - \dfrac{h_f h_r}{h_i + R_s} = \dfrac{1}{Z_o}$
$A_P = A_V A_i = A_i^2 \dfrac{R_L}{Z_i}$

Steps for ac analysis of a transistor circuit

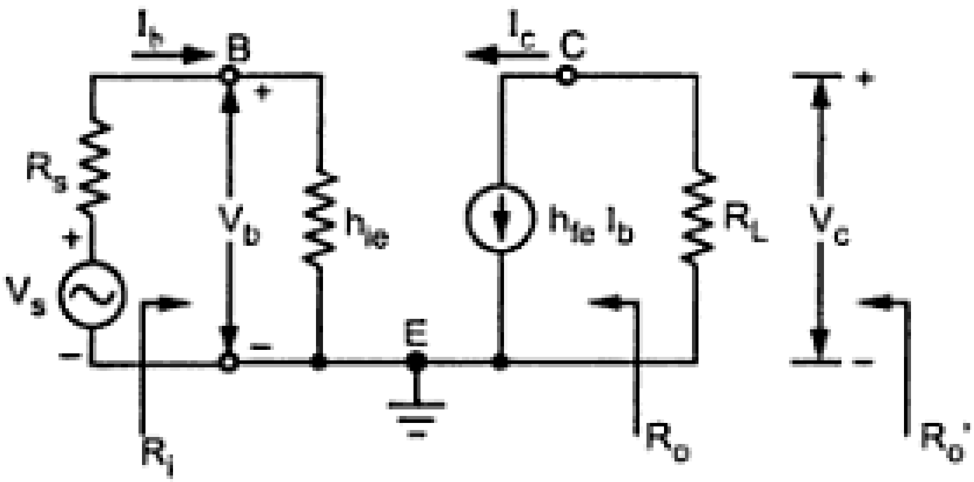
1. Draw the actual circuit diagram.
2. Replace coupling capacitors and emitter bypass capacitor by short circuit.
3. Replace dc source by a short circuit. In other words, short V_{CC} and ground lines.
4. Mark the points B(base), C(collector), E(emitter) on the circuit diagram and locate these points as the start of the equivalent circuit.
5. Replace the transistor by its h-parameter model.

Design Problem

➡ *Consider a single stage CE amplifier with* $R_s = 1\ k\Omega$, $R_1 = 50\ K$, $R_2 = 2K$, $R_C = 1K$, $R_l = 1.2\ K$, $h_{fe} = 50$, $h_{ie} = 1.1\ K$, $h_{oe} = 25\ \mu A/V$ *and* $h_{re} = 2.5 \times 10^{-4}$, *as shown in Fig.*



Approximate H-Model For CE Amplifier



Approximate CE model

Current Gain $A_i \approx -h_{fe}$

Input Impedance $R_i \approx h_{ie}$

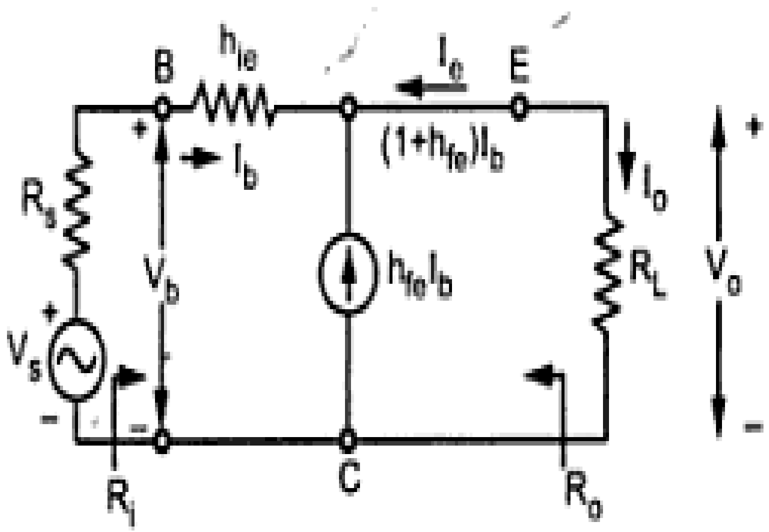
Voltage Gain : $A_v = \frac{A_i R_L}{R_i} = \frac{A_i R_L}{h_{ie}}$

Output Impedance $Y_o = 0$

$R_o = \frac{1}{Y_o} = \infty$

$R_o' = R_o \parallel R_L = \infty \parallel R_L = R_L$

Approximate H-Model For CC Amplifier



Simplified CC model

Current gain $A_i = \frac{I_o}{I_b} = \frac{-I_e}{I_b} = 1 + h_{fe}$

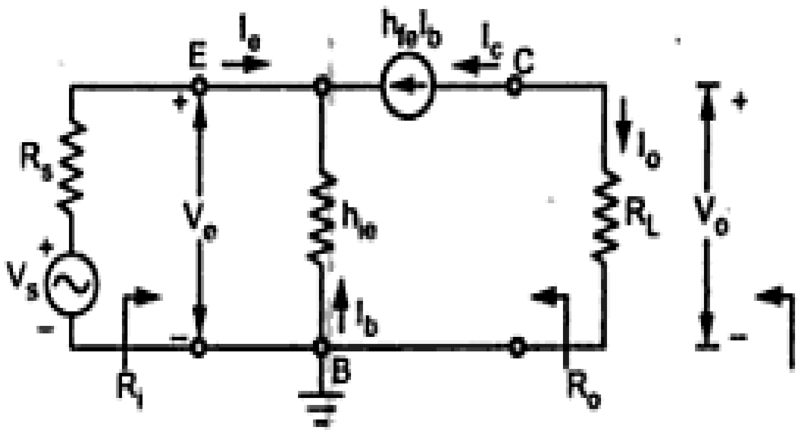
Input resistance : $R_i = \frac{V_b}{I_b} = h_{ie} + (1 + h_{fe})\, R_L$

Voltage gain (A_v) $A_v = \frac{(1 + h_{fe})\, R_L}{h_{ie} + (1 + h_{fe})\, R_L} \cong 1$

Output resistance R_o $R_o = \frac{V_o}{I_e} = \frac{R_s + h_{ie}}{1 + h_{fe}}$

$R'_o = R_o \parallel R_L = \infty \parallel R_L = R_L$

Approximate H-Model For CB Amplifier



Simplified CB model

Current gain $\quad A_i = \dfrac{h_{fe}}{1 + h_{fe}}$

Input resistance (R_i) $\quad R_i = \dfrac{h_{ie}}{1 + h_{fe}}$

Voltage gain (A_v) $\quad A_v = \dfrac{\dfrac{h_{fe}}{1+h_{fe}} \times R_L}{\dfrac{h_{ie}}{1+h_{fe}}} \doteq \dfrac{h_{fe}R_L}{h_{ie}}$

Output resistance (R_o) $\quad R_o = \left.\dfrac{V_o}{I_c}\right|_{V_s=0}$

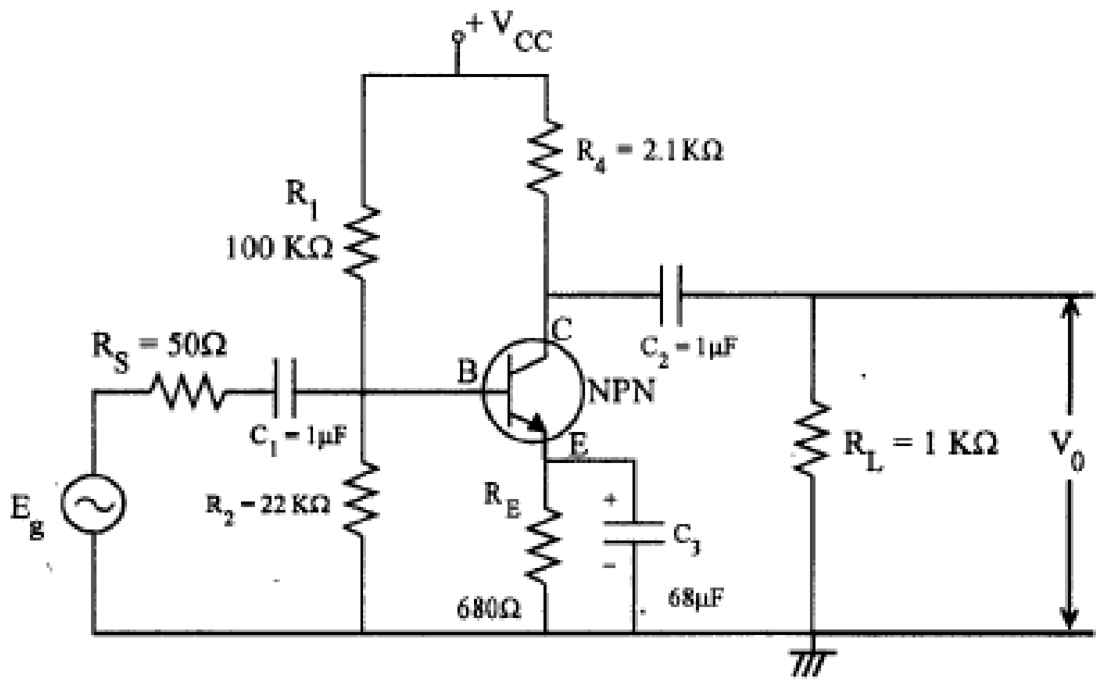
$$R'_o = R_o \parallel R_L = \infty \parallel R_L = R_L$$

Design Problem

For the circuit shown in Fig. estimate A_I, A_v, R_i and R_o using reasonable approximations. The ***h-parameters*** for the transistor are given as

$h_{fe} = 100$ $h_{ie} = 2000\ \Omega$ h_{re} is negligible and $h_{oe} = 10^{-5}$ mhos(℧).

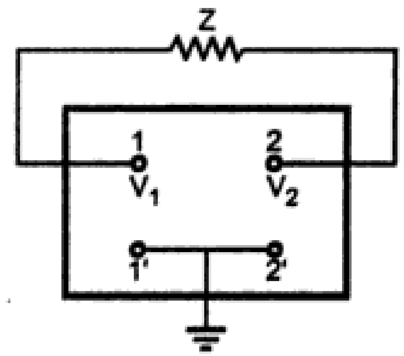
$I_b = 100\ \mu A$.



CE Amplifier Circuit

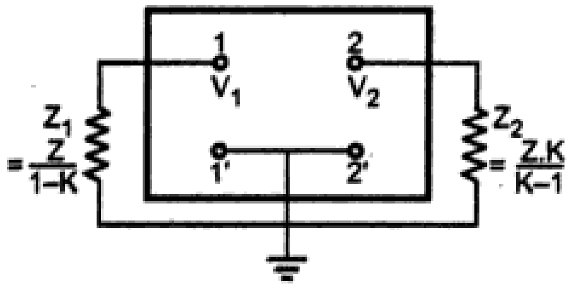
Miller 's Theorem

Millers theorem is used to simplify the analysis of a circuit
whenever there is a feedback connection in the circuit



(a)

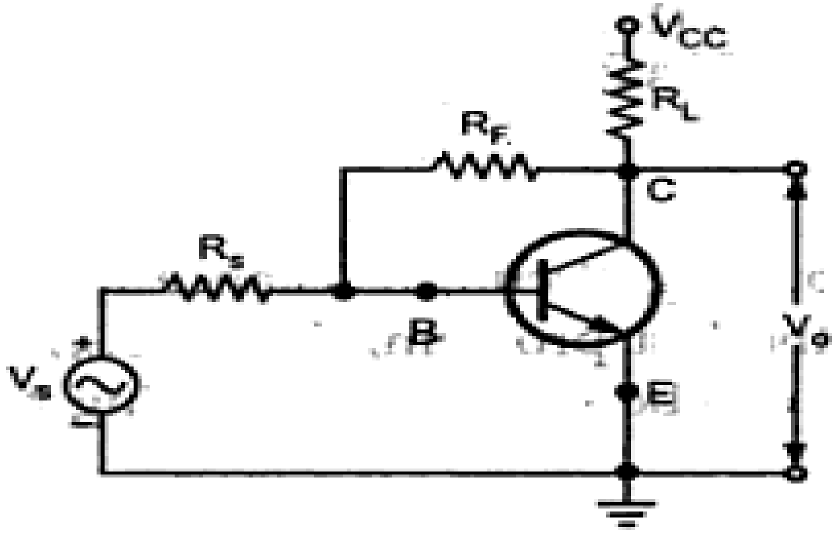
$$Z_1 = \frac{Z}{1-K}$$

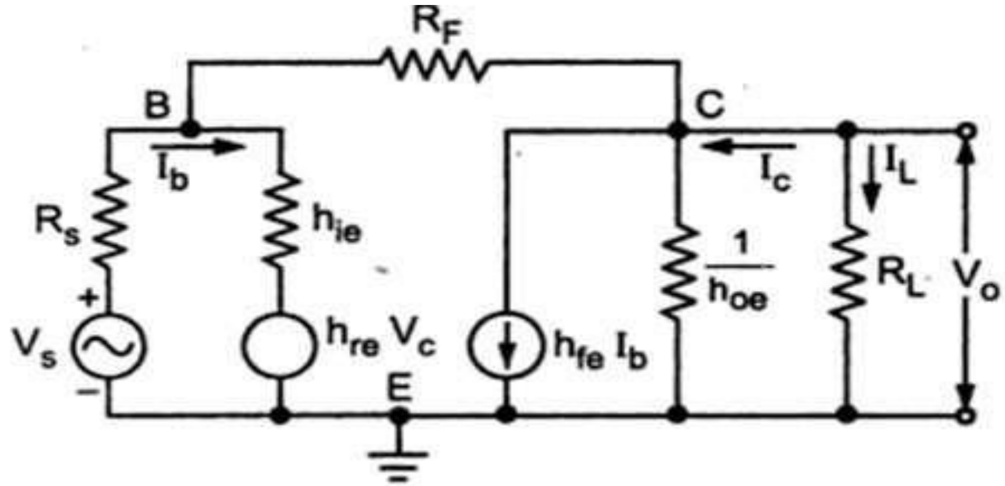


(b)

$$Z_2 = \frac{Z \cdot K}{K-1}$$

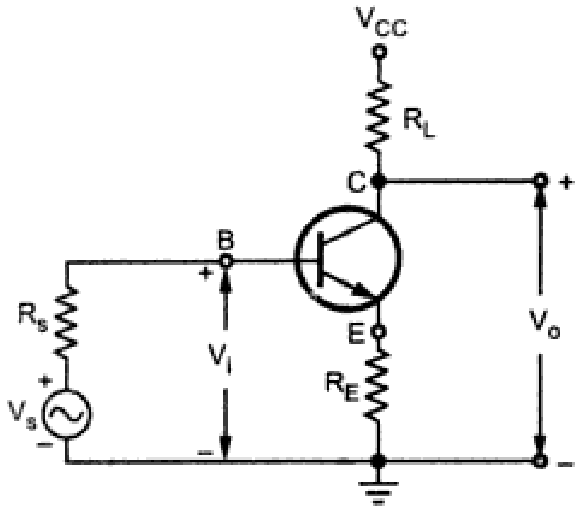
Analysis of Common Emitter Amplifier with Collector to Base Bias





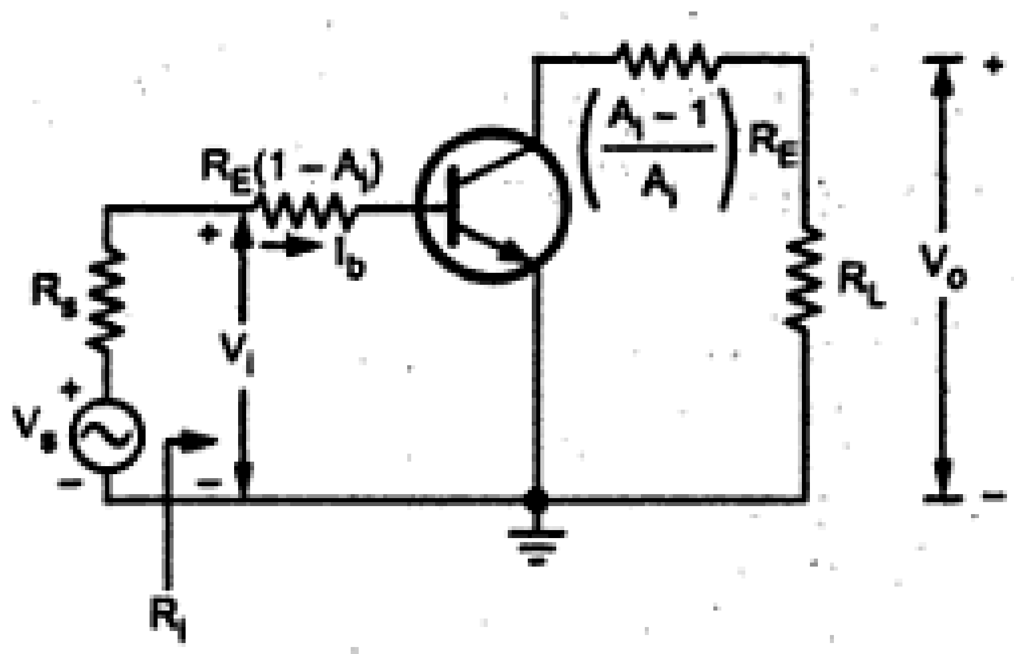
AC equivalent circuit

Analysis Of CE Amplifier With Unbypassed R_E

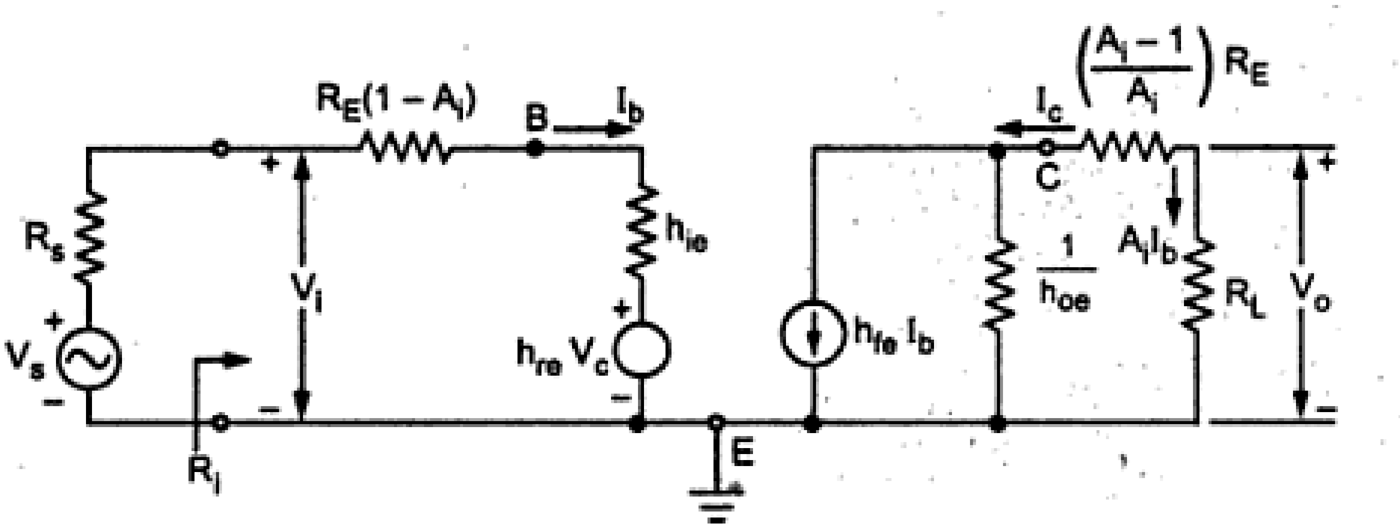


- ❖ R_E is added to stabilize the gain of the amplifier
- ❖ R_E acts as a feedbackresistor
- ❖ The overall gain will reduce with unbypassed R_E

AC Equivalent Circuit For CE Amplifier with R_E Splitted using dual of Miller's Theorem

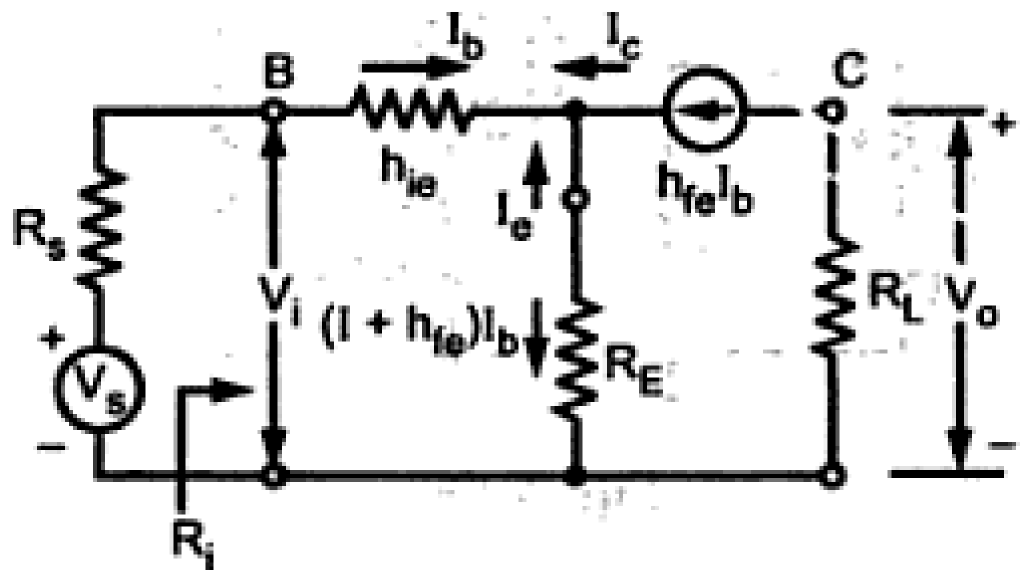


h-Parameter Equivalent Circuit (Exact Analysis)



$$A_i = \frac{-h_{fe}}{1+h_{oe}R_L'} = \frac{-h_{fe}}{1+h_{oe}\left(R_L + \frac{A_i - 1}{A_i} R_E\right)}$$

h-Parameter Equivalent Circuit (Approximate Analysis)



Approximate model for CE amplifier with R_E

Design Parameter

Current gain $A_i = \frac{-I_c}{I_b} = \frac{-h_{fe} I_b}{I_b} = -h_{fe}$

Input resistance $R_i = \frac{V_i}{I_b} = h_{ie} + (1 + h_{fe}) R_E$

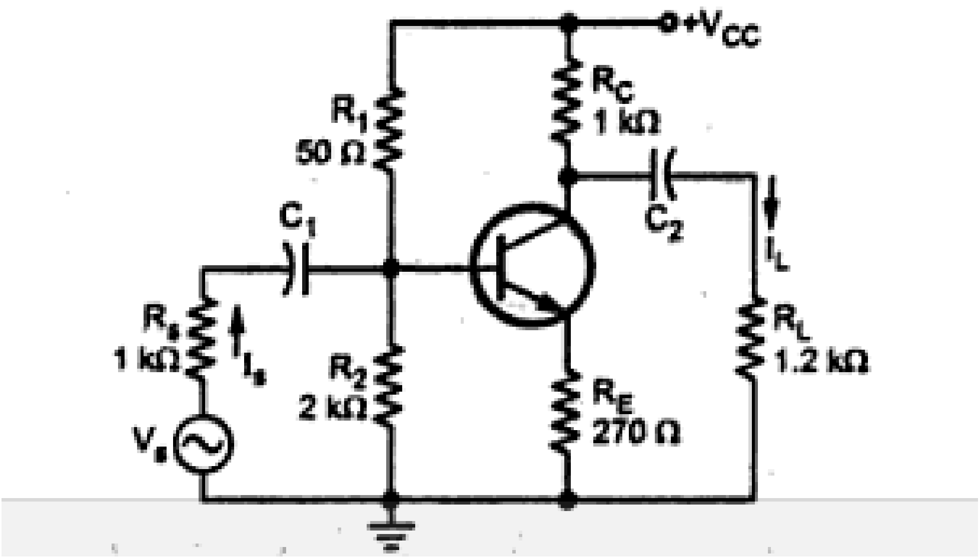
Voltage gain $A_v = \frac{A_i R_L}{R_i} = \frac{-h_{fe} R_L}{h_{ie} + (1 + h_{fe}) R_E}$

Output resistance $R_o = \left.\frac{V_o}{I_o}\right|_{V_s = 0}$

$R'_o = R_o \parallel R_L = \infty \parallel R_L = R_L$

Design Problems

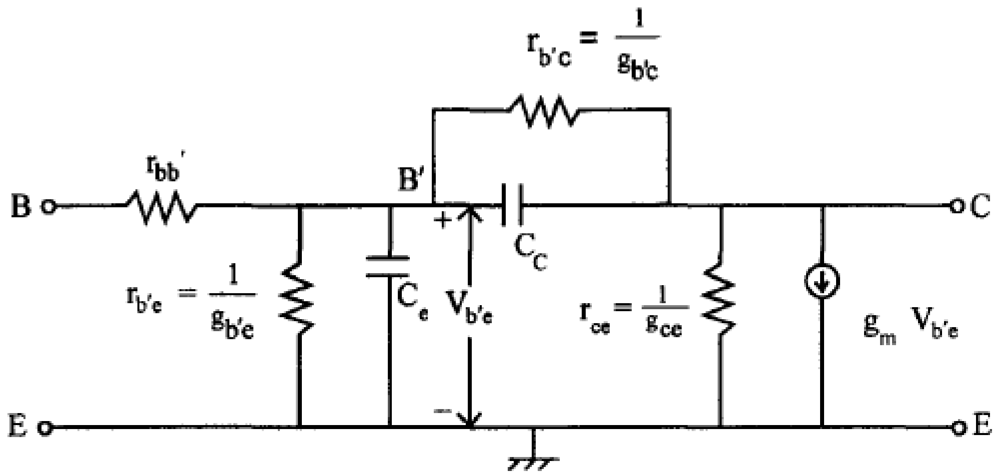
Example *Fig. shows a single stage CE amplifier with unbypassed emitter resistance find current gain, input resistance, voltage gain and output resistance. Use typical values of h-parameter*



UNIT-II

HIGH FREQUENCY RESPONSE OF AMPLIFIER

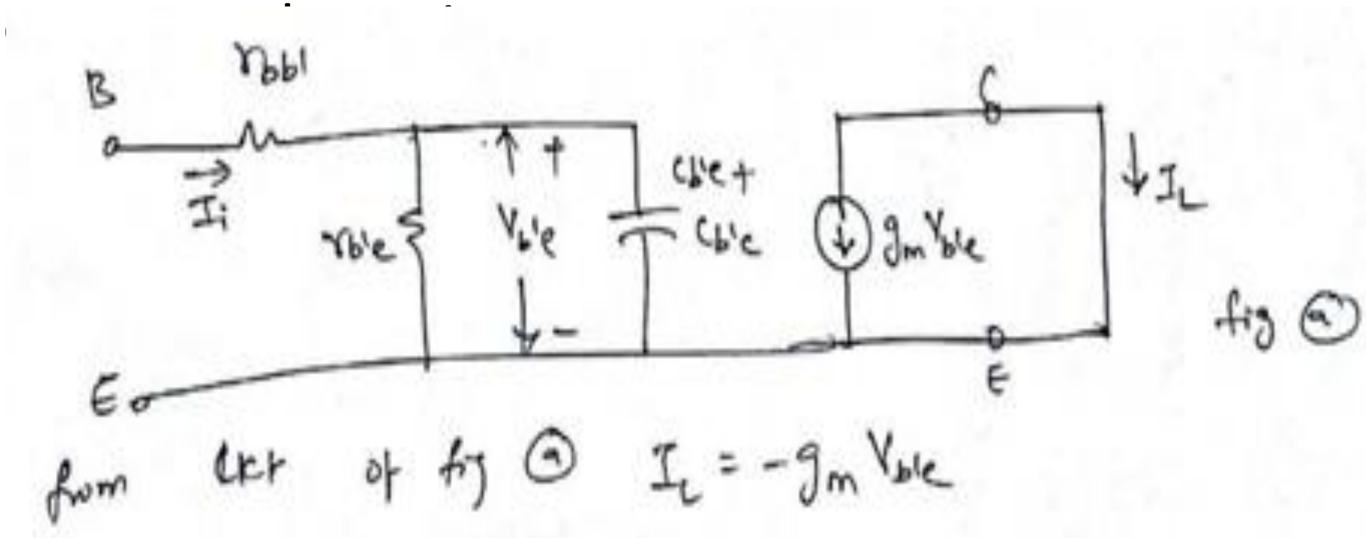
The hybrid-π common emitter transistor model



Hybrid - π C.E BJT Model

common emitter short circuit current gain

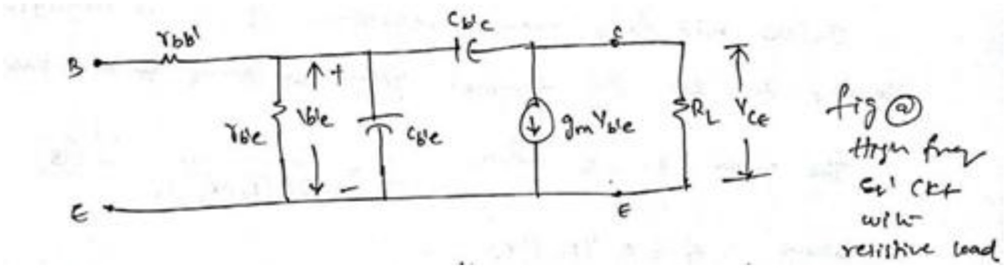
- The transistors high frequency capability can be known, if is CE S.C forward. Current transfer ratio or current gain is found as function of frequency.
- As R_L is socket the approximate. High frequency model be



$$A_i = \frac{-hf_e}{1 + j\dfrac{f}{f_\beta}}$$

current gain with resistive load

- With a resistive load connected in the output, the high frequency sq ckt of a CE transistor amplifier is shown in fig (a) by using miller’s theorem the ckt of fig (a) can be modified as described below.



- From fig (a) the voltage gain

$$A = -g_m R_L$$

$$1 - A = 1 + g_m R_L$$

- Fig (a) high frequency eq ckt with resistive load since the impedance at the i\p gets decreased by a factor (1-A) the capacitance will be increased by a factor of (1-A) or if .
- The capacitance that is to be included in the o\p ckt will not make any significant change in the performance and may be neglected. This result in the modified eq ckt of fig (b)
- The total i\p capacitance between B & E is

$$R^{1} = \frac{(R_{S}^{1} + \Upsilon_{bb^{1}})\Upsilon_{b^{1}e}}{R_{S}^{1} + h_{fe}}$$

$$R_{s}^{1} = R_{s} \,||\, R_{B}$$

alpha, beta cut-off frequencies

$$f_{\alpha} = \frac{h_{fe}}{2\Pi r_{b^1e} C_{b^1e}}$$

$$f_{\beta} = \frac{f_T}{h_{fe}}$$

gain bandwidth product

- f_T is defined as the frequency at which the s.c CE current gain has a magnitude of unity

$$f_T = h_{fe} f_\beta$$

- All the resistance components in the hybrid-pi model can be obtained from the h parameters in CE configuration.

1.Transistor Transconductance $(g_m) = |I_C| / V_T$

2.The Input Conductance $(g_{b^1 e}) = g_m / h_{fe}$

3.The Feedback Conductance $(g_{b^1 c}) = h_{re}\, g_{b^1 e}$

4.The Base Spreading Resistance $(r_{b^1 b}) = h_{ie} - r_{b^1 e}$

5. The Output Conductance $(g_{ce}) = h_{oe} - (1+h_{fe})\, g_{b^1 c}$

- There are basically two types of capacitances in pn junction diode i.e. one is junction capacitance and other is diffusion capacitance

- The active mode BJT has one forward biased pn junction and one reverse biased pn junction. in case of npn BJT the capacitances associated with pn junctions are labeled as

1. C_{μ} =junction capacitance associate with reversed biased CBJ
2. C_{je} = junction capacitance associate with forward biased EBJ
3. C_{de}=diffusion capacitance associate with forward biased EBJ

- The diffusion capacitance and junction capacitance associated with forward biased EBJ are appeared parallel and can be combined as $C_{\pi} = C_{je} + C_{de}$

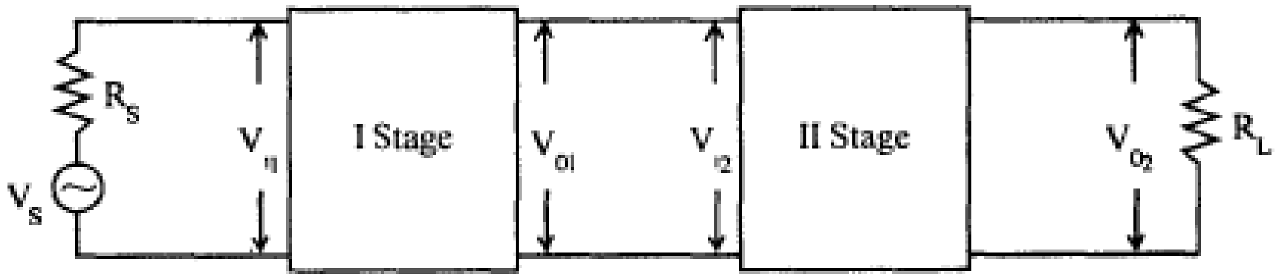
UNIT-III

MULTI STAGE AMPLIFIERS AND TUNED AMPLIFIERS

Need For Cascading

- When the amplification of a single stage amplifier is not sufficient, or,
- When the input or output impedance is not of the correct magnitude, for a particular application two or more amplifier stages are connected, in cascade. Such amplifier, with two or more stages is also known as multistage amplifier.

Block diagram of 2-Stage Cascade Amplifier



Gain

$$G_1 = \frac{P_2}{P_1}; \quad G_2 = \frac{P_3}{P_2}$$

Overall gain $$G = \frac{P_3}{P_1}$$

$$= \frac{P_2}{P_1} \cdot \frac{P_3}{P_2}$$

$$\mathbf{G = G_1\, G_2}$$

Decibel Voltage Gain

Cascaded Stages

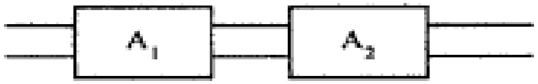


Fig. 2.23 Cascaded stages

$$A = A_1 \times A_2$$

$$A_1 = A_1' + A_2' \text{ (in decibels)}$$

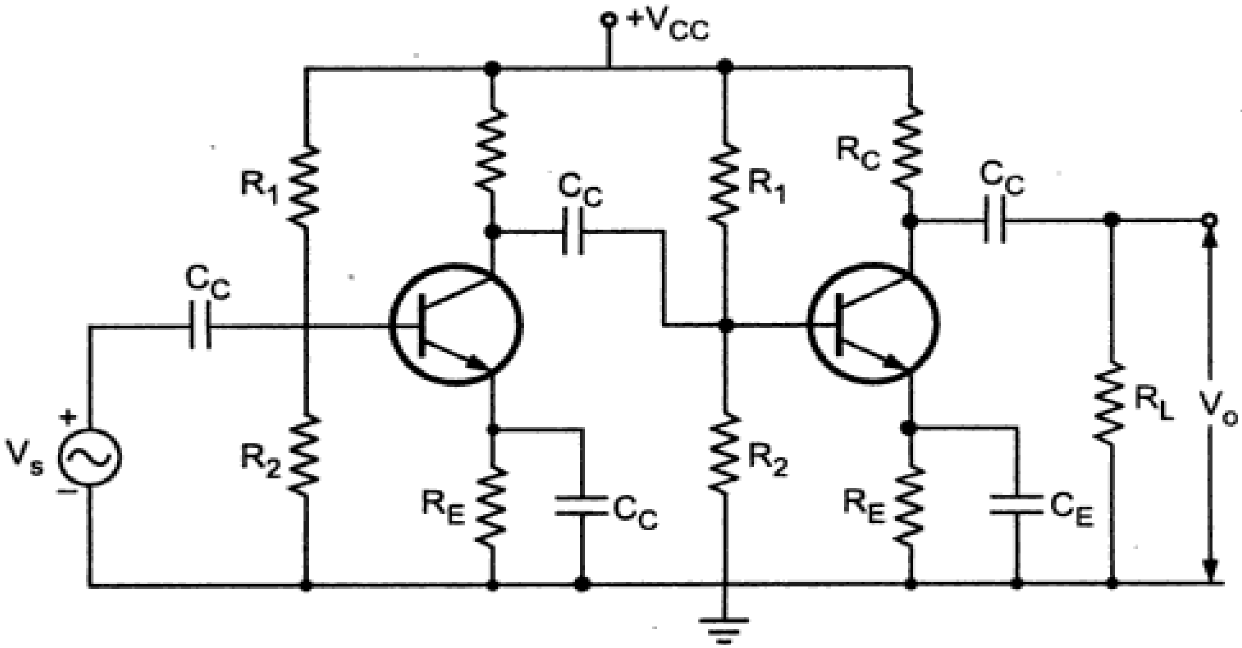
Coupling Schemes

Methods of Inter Stage Coupling

In multistage amplifier, the output signal of preceding stage is to be coupled to the input circuit of succeeding stage. For this interstage coupling, different types of coupling elements can be employed. These are :

1. RC coupling
2. Transformer coupling
3. Direct coupling

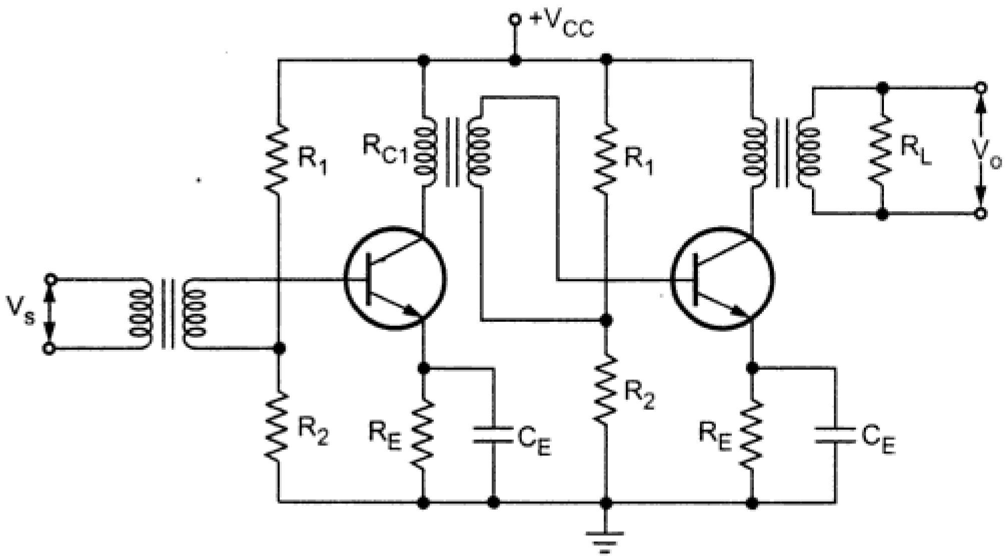
RC coupling



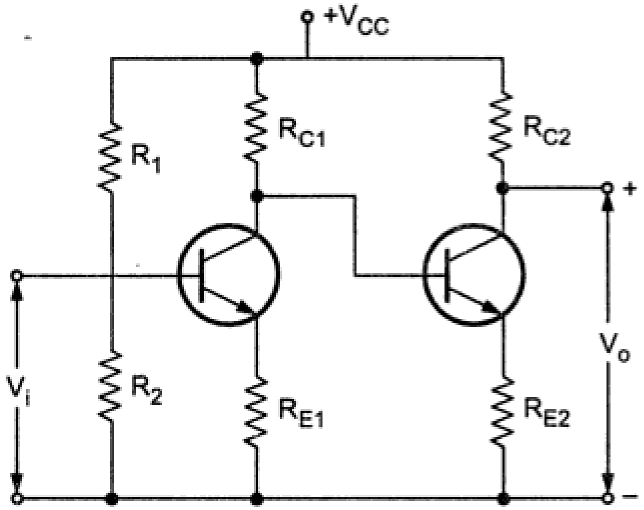
Two stage RC coupled amplifier using transistors

Transformer coupling

Two stage transformer coupled amplifier using transistors



Direct coupling



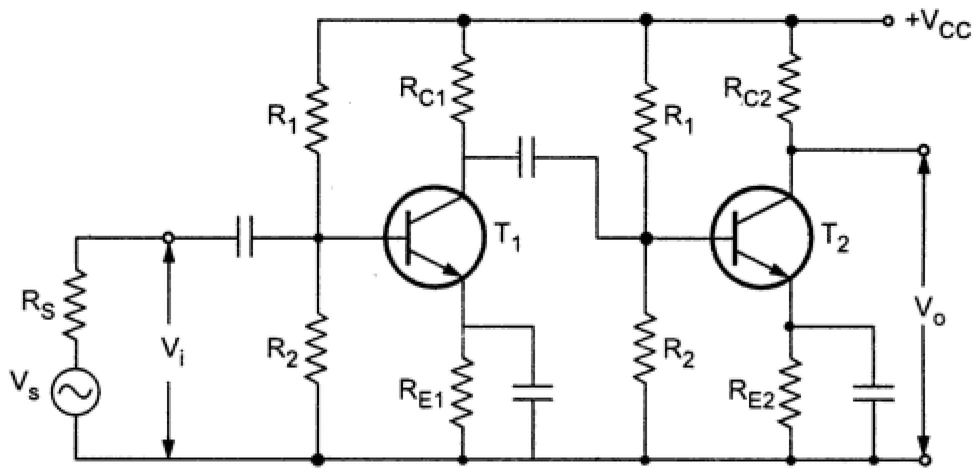
Two stage directly coupled amplifier using transistors

Frequency Response of 2-Stage RC Coupled Amplifier

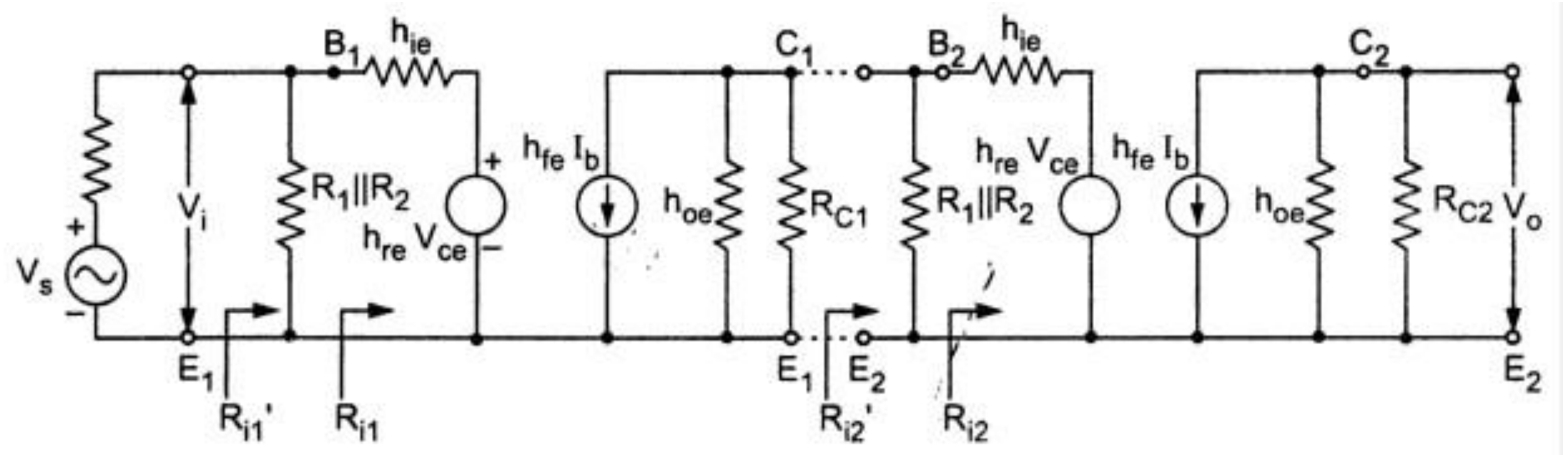
Comparison Between Coupling Method

Parameter	RC Coupled	Transformer Coupled	Direct Coupled
Coupling Components	Resistor and Capacitor	Impedance matching transformer	–
Block DC	Yes	Yes	No
Frequency response	Flat at middle frequencies	Not uniform, high at resonant frequency and low at other frequencies	Flat at middle frequencies and improvement in the low frequency response
Impedance matching	Not achieved	Achieved	Not achieved
DC amplification	No	No	Yes
Weight	Light	Bulky and heavy	
Drift	Not present	Not present	Present
Hum	Not present	Present	Not present
Application	Used in all audio small signal amplifiers. Used in record players, tape recorders, public address systems, radio receivers and television receivers.	Used in amplifier where impedance matching is an important criteria. Used in the output stage of the pubic address system to match the impedance of loudspeaker. Used in the RF amplifier stage of the receiver as a tuned voltage amplifier.	Used in amplification of slow varying parameters and where DC amplification is required.

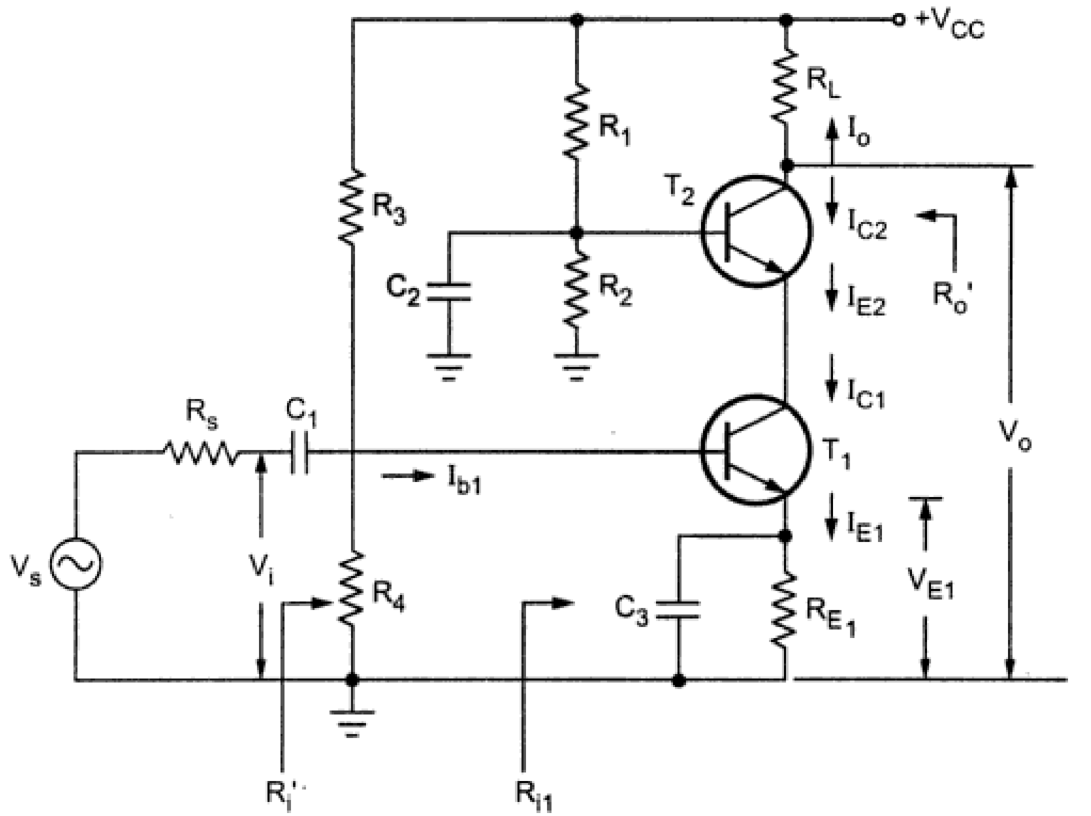
CE-CE Cascade Amplifier



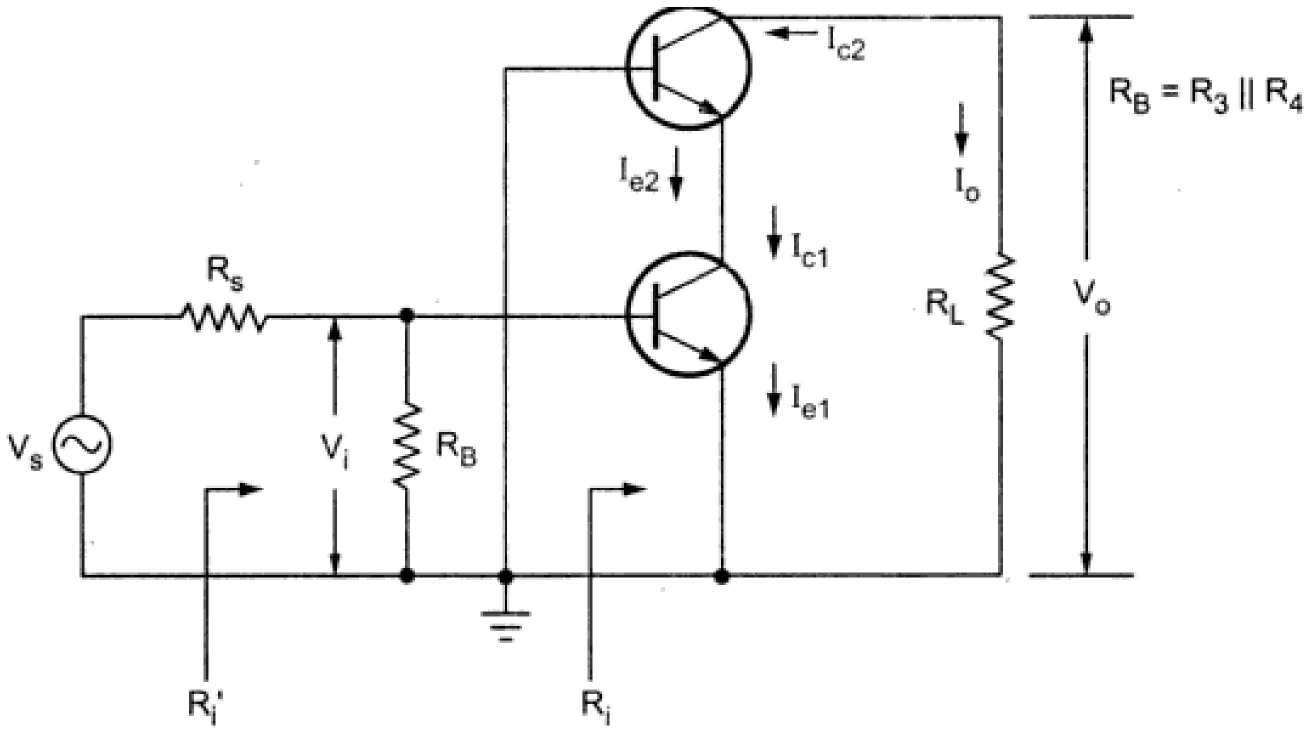
h-parameter equivalent circuit for CE-CE cascade amplifier



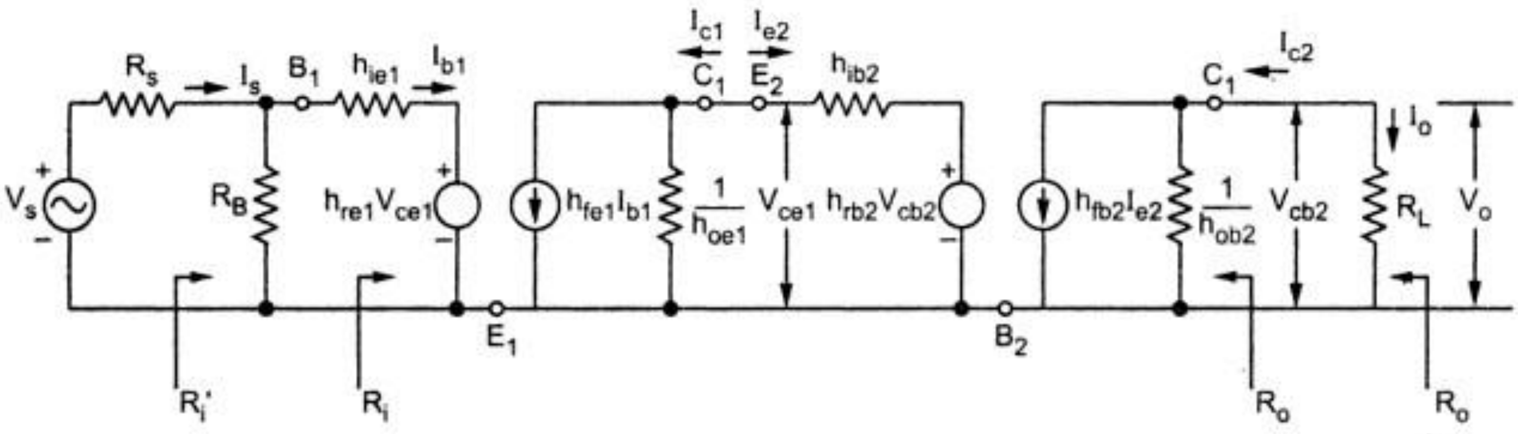
Cascode Amplifier



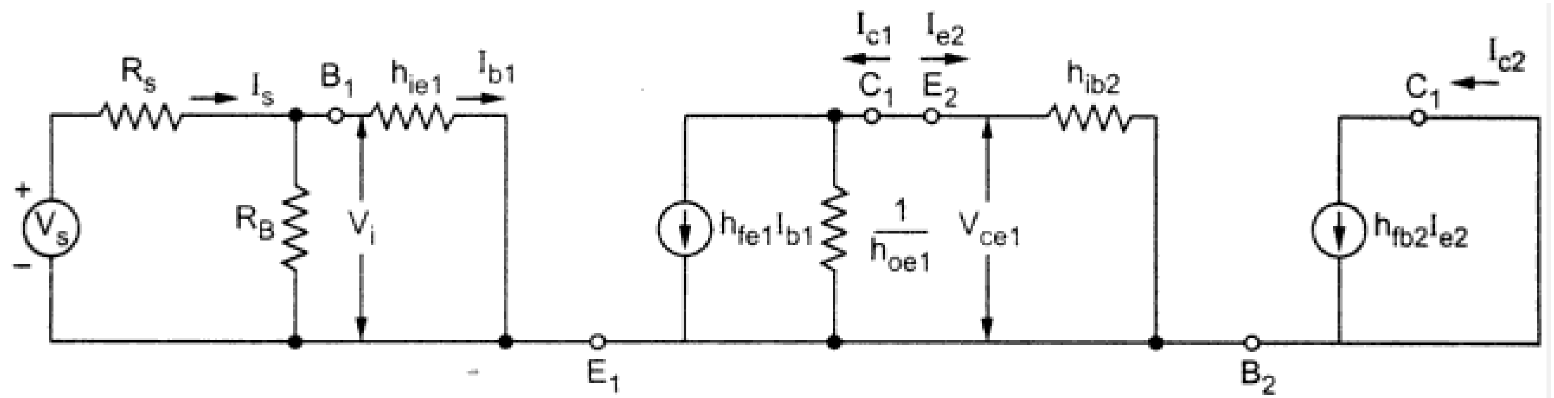
AC equivalent circuit



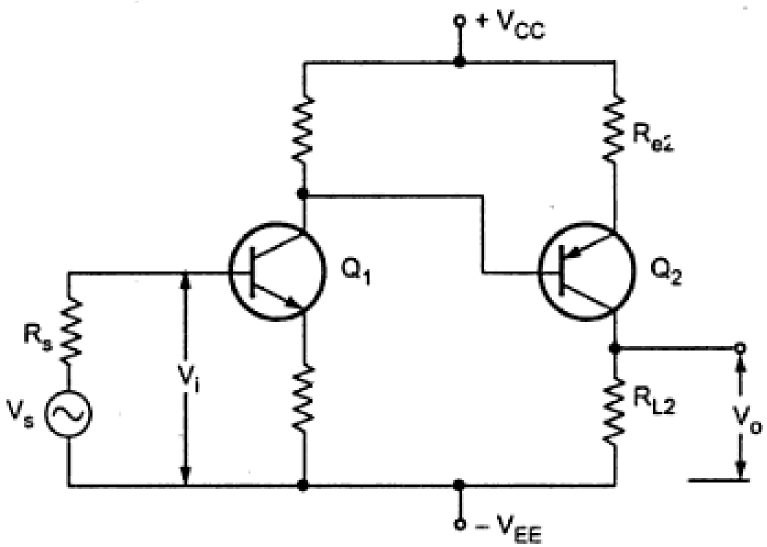
h-parameter equivalent circuit for cascode amplifier



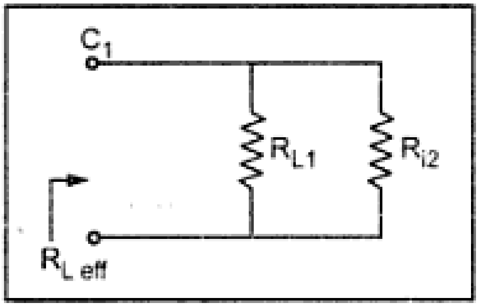
h-parameter equivalent circuit when output shorted



CE-CC Amplifier

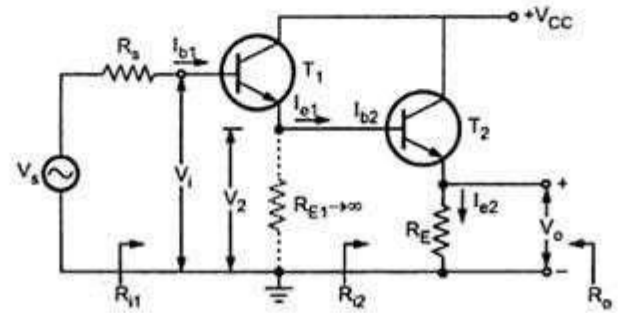


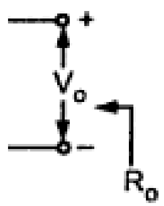
Analysis for first stage



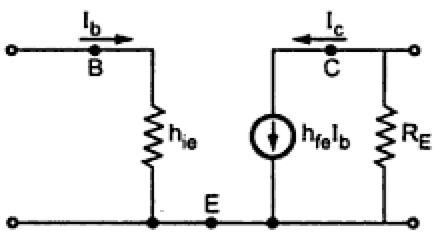
Darlington Transistors

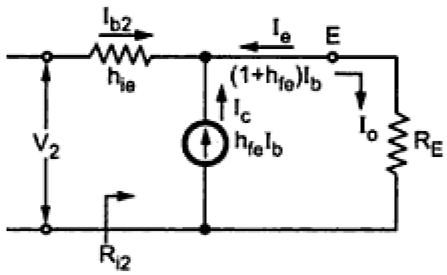
Darlington Transistors $+V_{CC}$

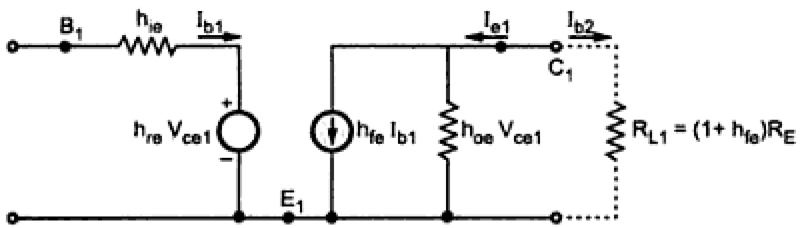




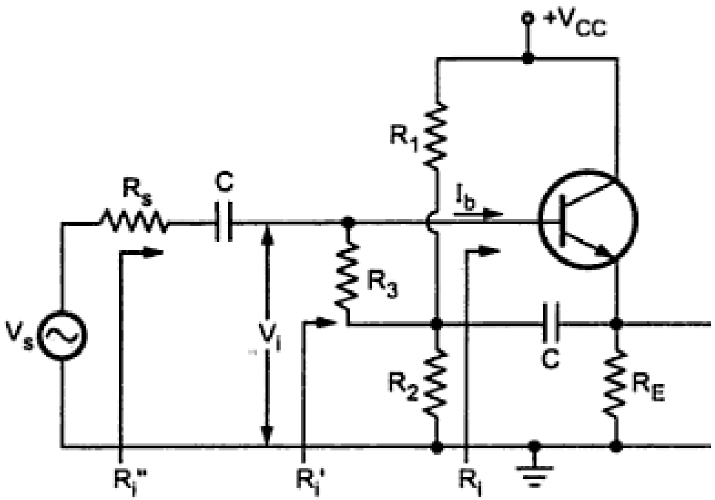
AC Equivalent Circuit :

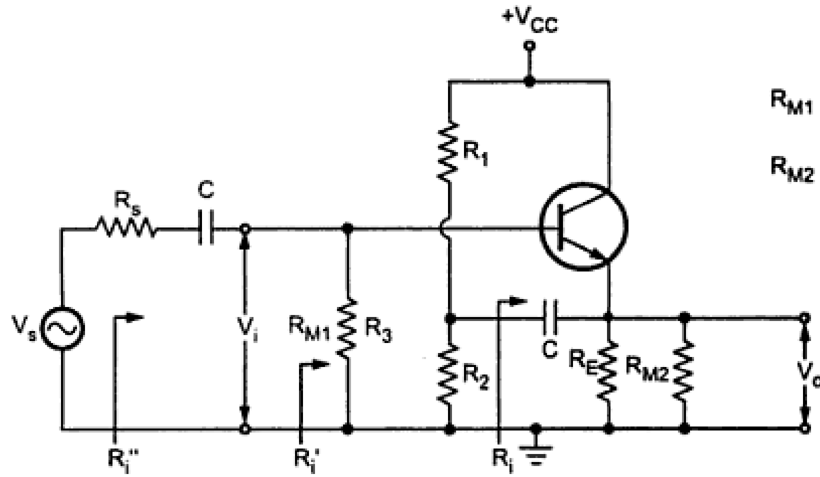






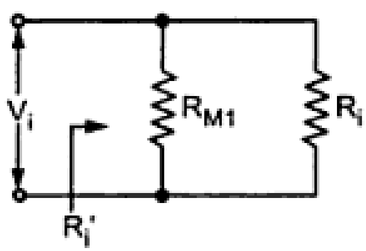
Bootstrap Emitter Follower



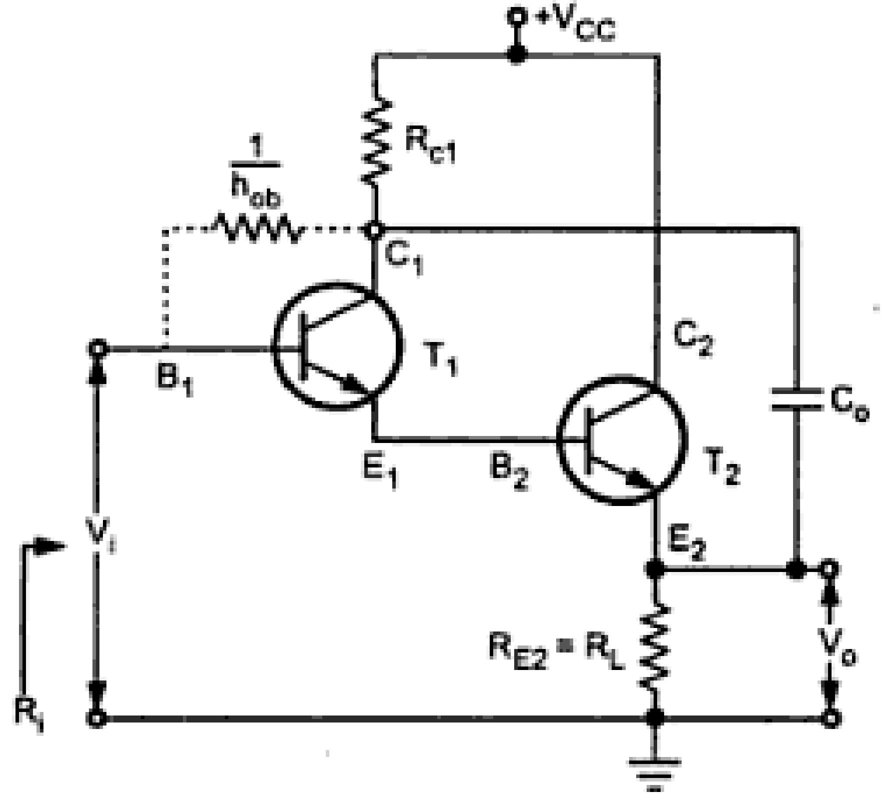


$$R_{M1} = \frac{R_3}{1 - A_v}$$

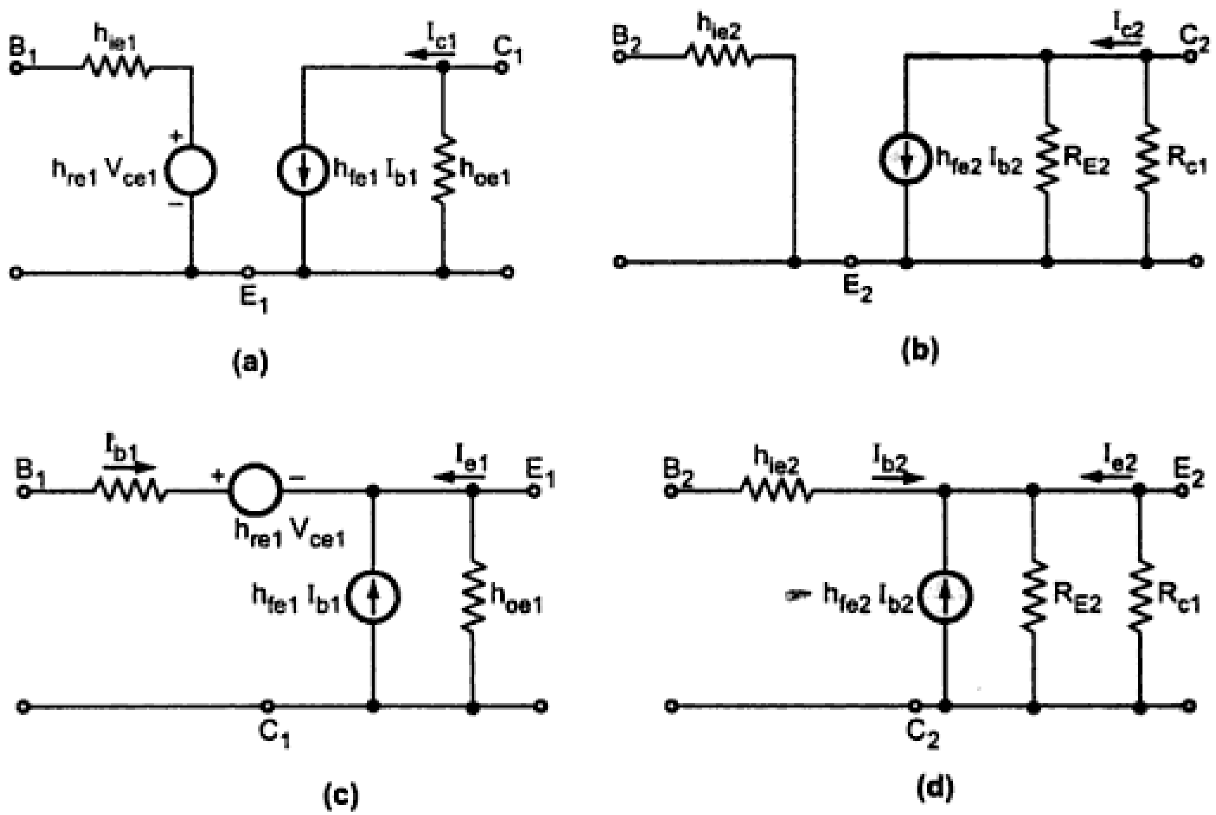
$$R_{M2} = \frac{R_3 A_v}{A_v - 1}$$

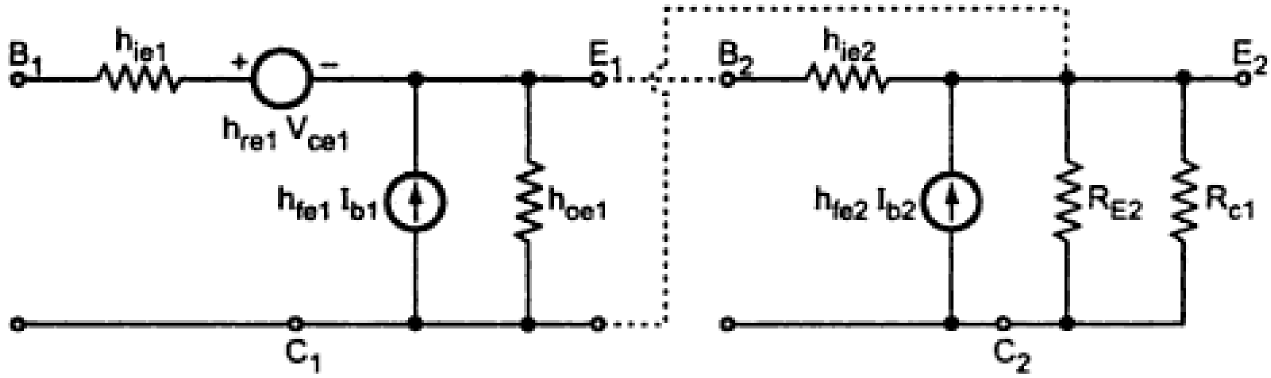


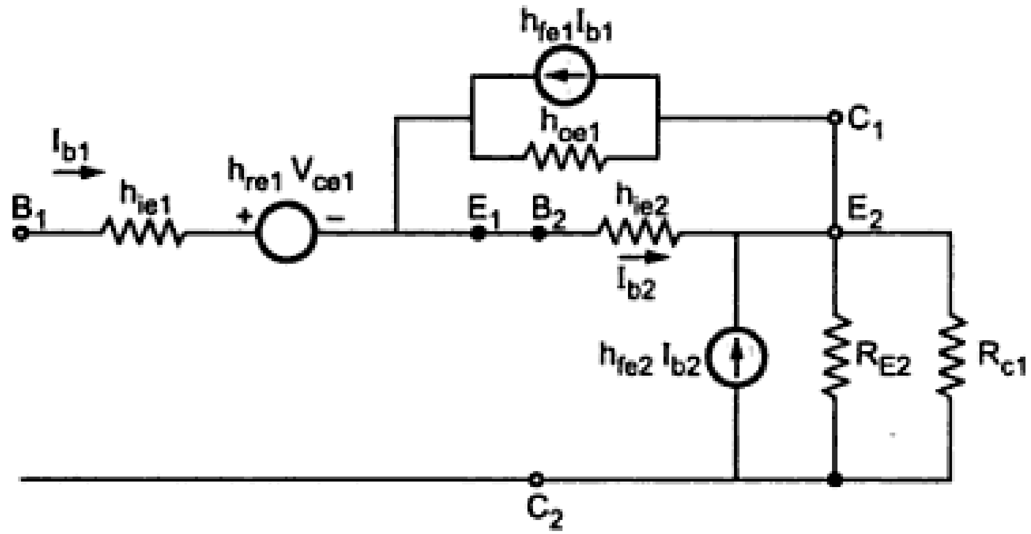
Bootstrapped Darlington circuit



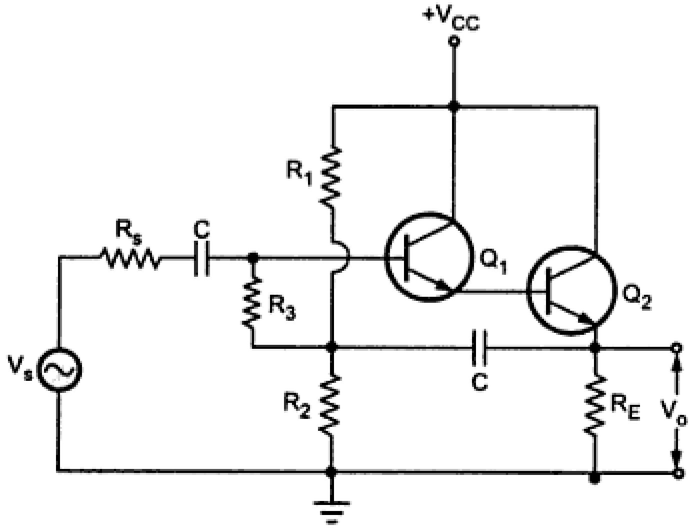
AC Equivalent circuit for bootstrapped Darlington circuit

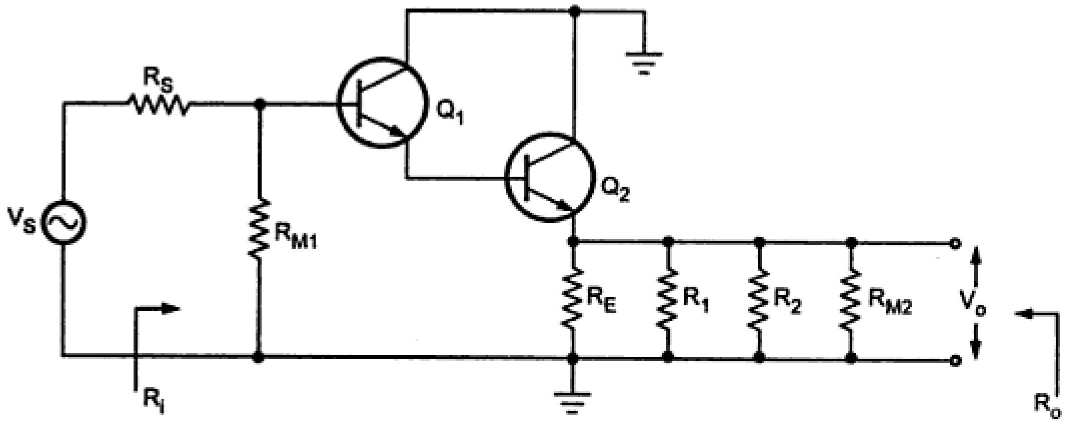



B1
hie1
hre1 Vce1
hfe1 Ib1
hoe1
E1
C1
B2
hie2
hfe2 Ib2
RE2
Rc1
E2
C2

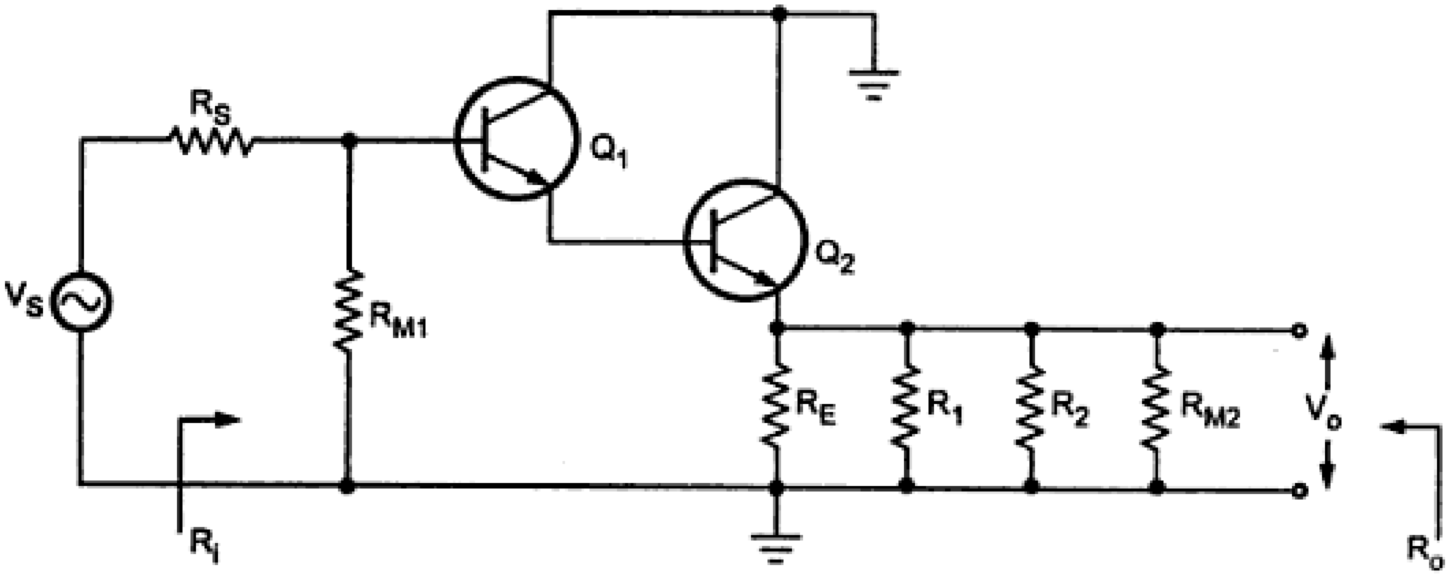

hfe1Ib1
hoe1
C1
Ib1
B1
hie1
hre1 Vce1
E1
B2
hie2
Ib2
E2
hfe2 Ib2
RE2
Rc1
C2

Bootstrapped Darlington Circuit Alternative Approach



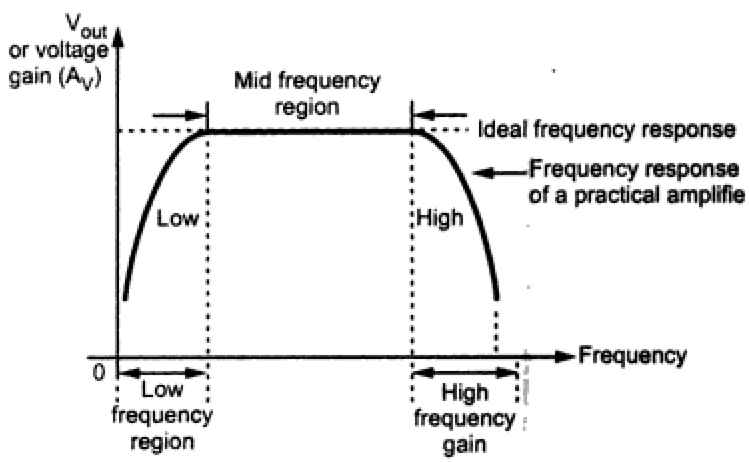


AC equivalent circuit

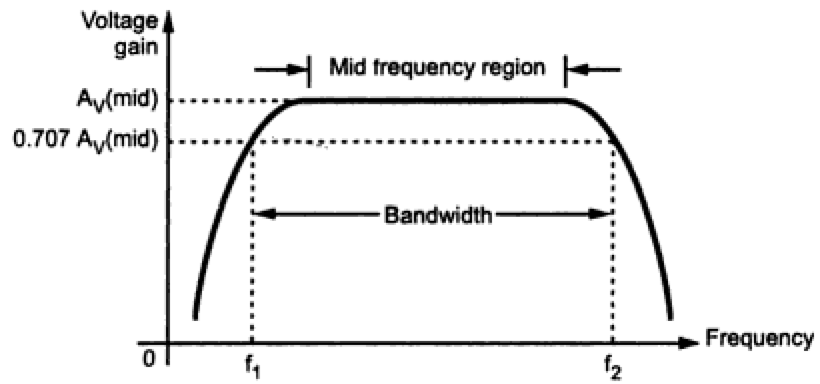


AC equivalent circuit

Frequency Response of an RC Coupled Amplifier



Bandwidth of an Amplifier



Frequency response, half power frequencies and bandwidth of an RC coupled amplifier

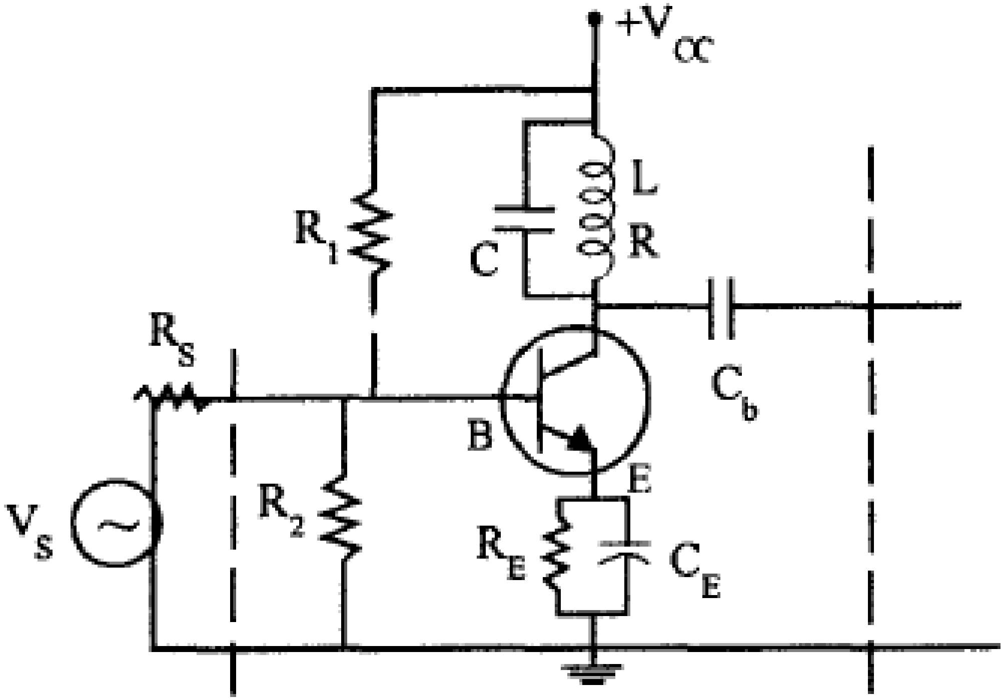
Single Tuned Amplifier

•Uses one parallel tuned circuit as the load IZI in each stage and all these tuned circuits in different stages are tuned to the same frequency. To get large Av or Ap, multistage amplifiers are used. But each stage is tuned to the same frequency, one tuned circuit in one stage.

Single tuned amplifiers are further classified as :

- Capacitive coupled
- Transformer coupled or inductive coupled

Single Tuned Capacitive Coupled Amplifier



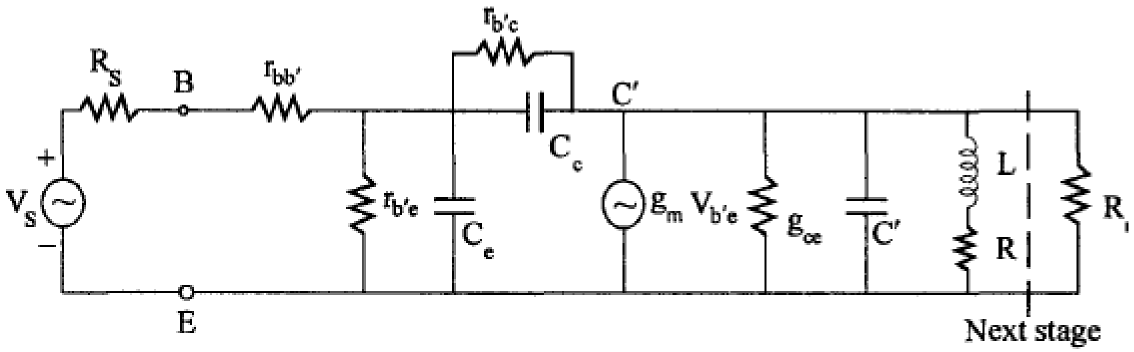
Single Tuned Amplifier

•Uses one parallel tuned circuit as the load IZI in each stage and all these tuned circuits in different stages are tuned to the same frequency. To get large Av or Ap, multistage amplifiers are used. But each stage is tuned to the same frequency, one tuned circuit in one stage.

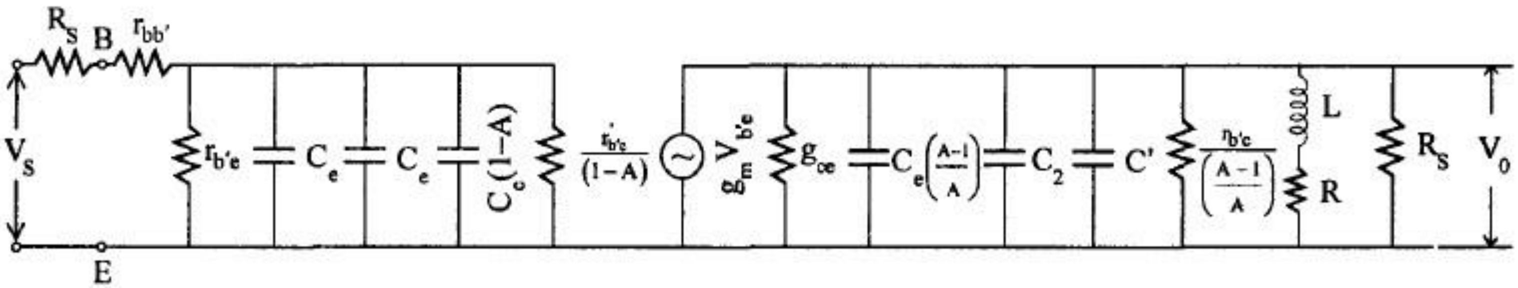
Single tuned amplifiers are further classified as :

- Capacitive coupled
- Transformer coupled or inductive coupled

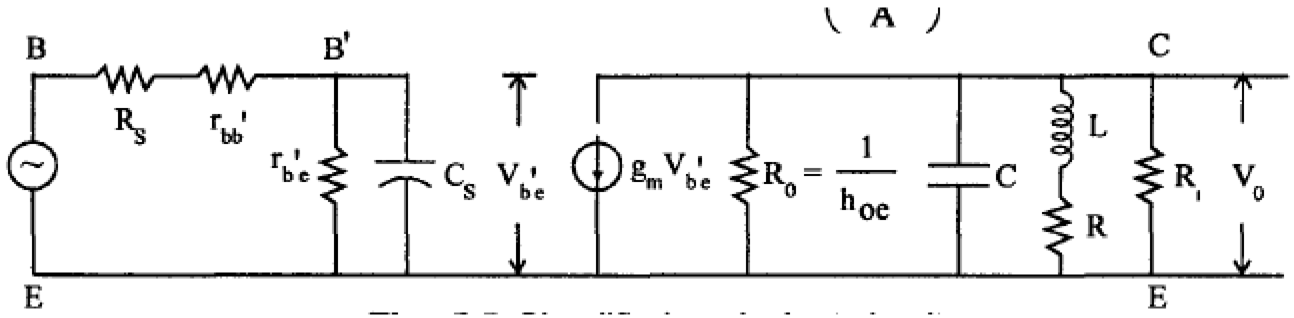
Equivalent circuit of Single Tuned Capacitive



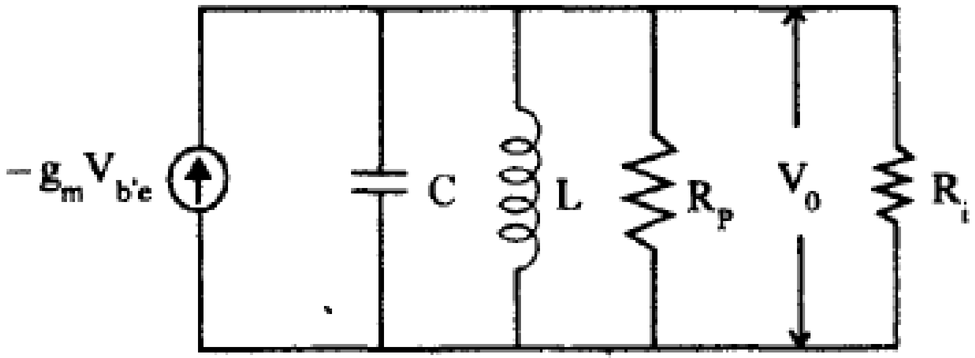
Equivalent circuit of Single Tuned Capacitive Coupled Amplifier(applying Miller's Theorem)



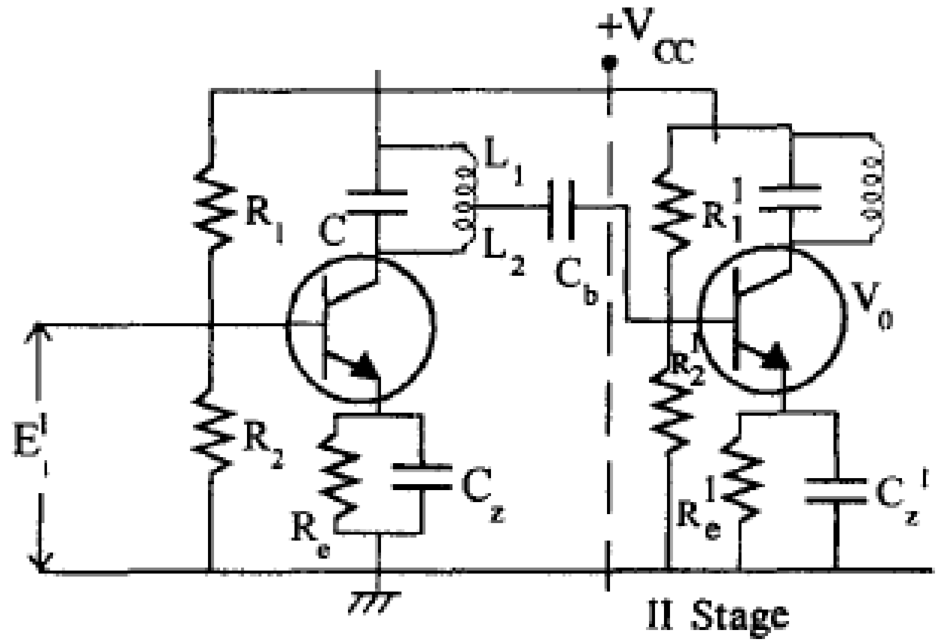
Simplified equivalent circuit



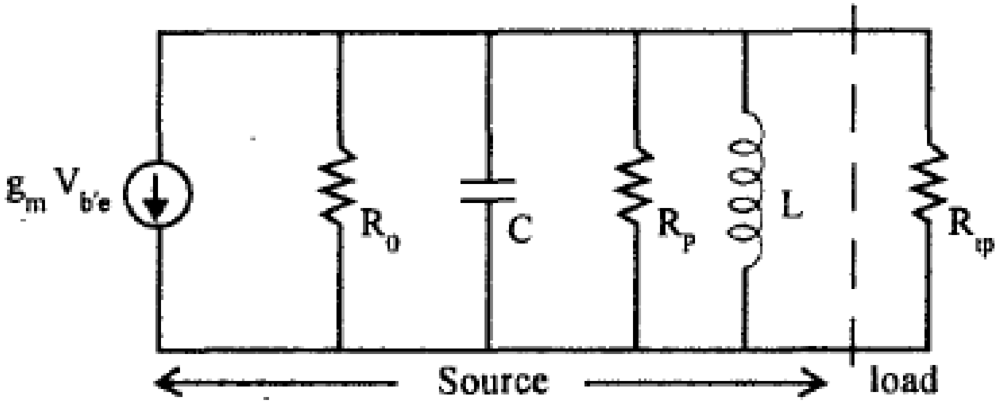
Simplified output circuit



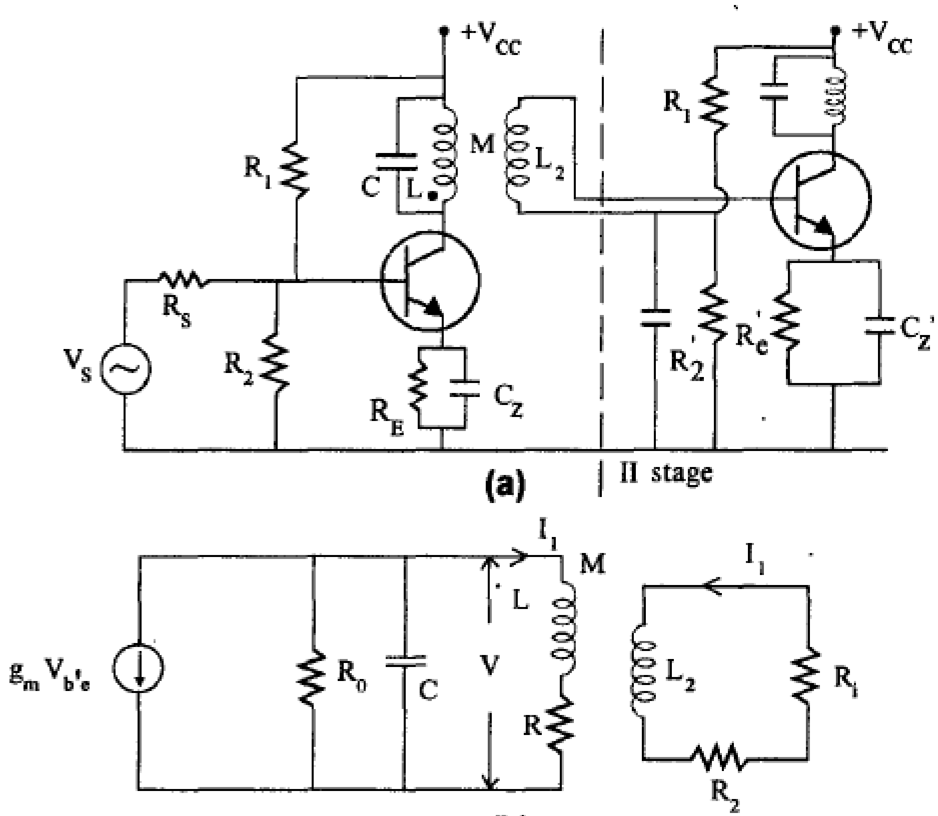
Tapped Single Tuned Capacitance Coupled Amplifier



Equivalent circuit of Tapped Single Tuned Capacitance



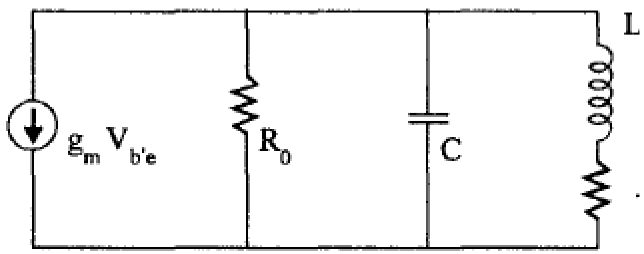
Single Tuned Transformer Coupled or Inductively Coupled Amplifier



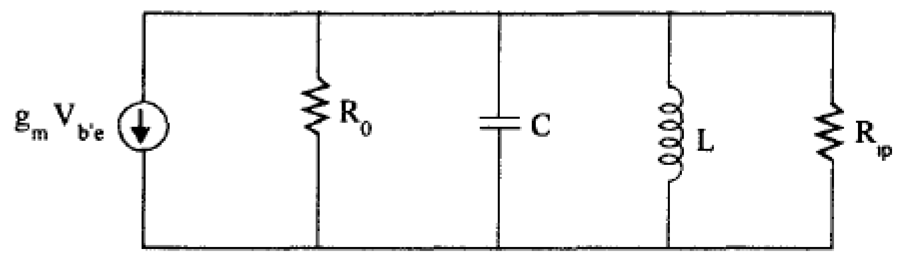
(a)

(b) Equivalent output circuit

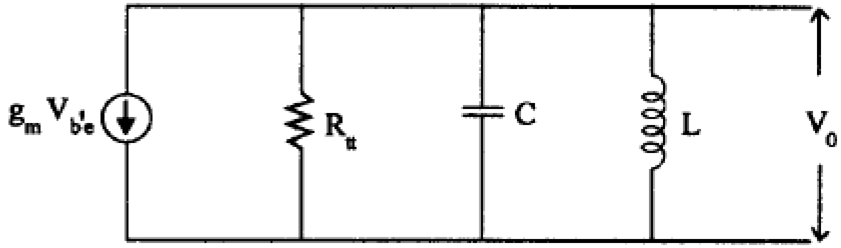
Single Tuned Transformer Coupled or Inductively Coupled Amplifier



(a)Equivalent circuit



(b)Simplified circuit

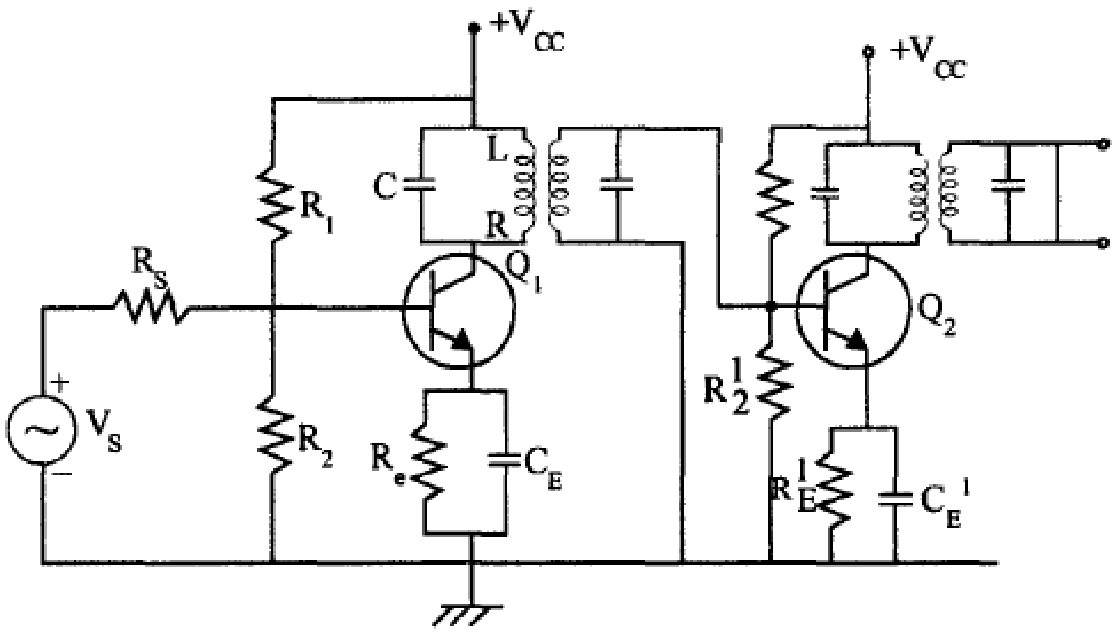


©Equivalent circuit

Double Tuned Amplifier

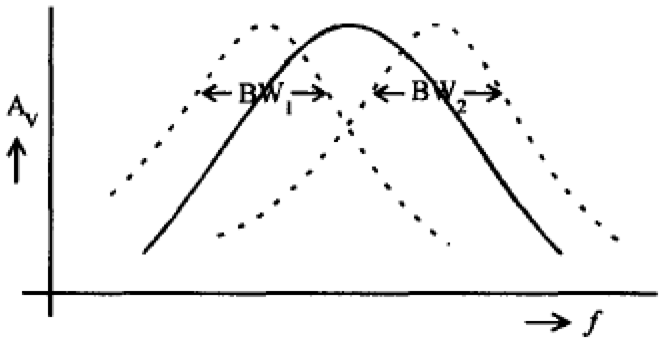
- It uses two inductively coupled tuned circuits, for each stage of the amplifier. Both the tuned circuits are tuned to the same frequency, two tuned circuits in one stage, to get sharp response.
- It provides larger 3-db band width than the single tuned amplifier. Therefore Gain x Bandwidth product is more.
- It provides gain - frequency curve having steeper sides and flatter top.

Double tuned amplifier circuit



Stagger Tuned Amplifier

•This circuit uses number of single tuned stages in cascade. The successive tuned circuits are tuned to slightly different frequencies.



Variation of Av with f

UNIT-IV

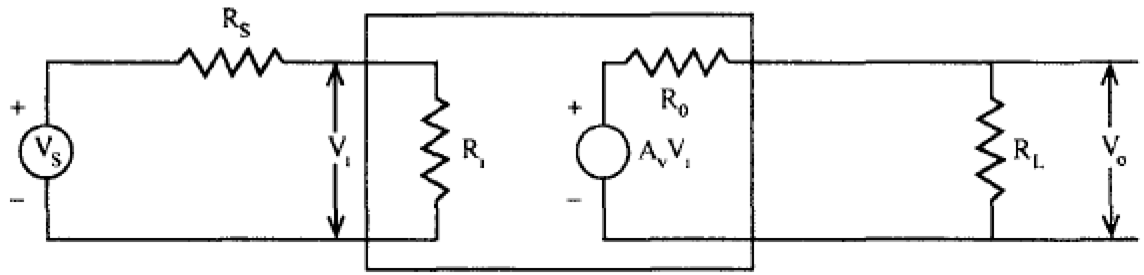
Feedback Amplifiers & Oscillators

CLASSIFICATION OF AMPLIFIERS

- Amplifiers can be classified broadly as,
- I. Voltage amplifiers.
- 2. Current amplifiers.
- 3. Transconductance amplifiers.
- 4. Transresistance amplifiers.

VOLTAGE AMPLIFIER

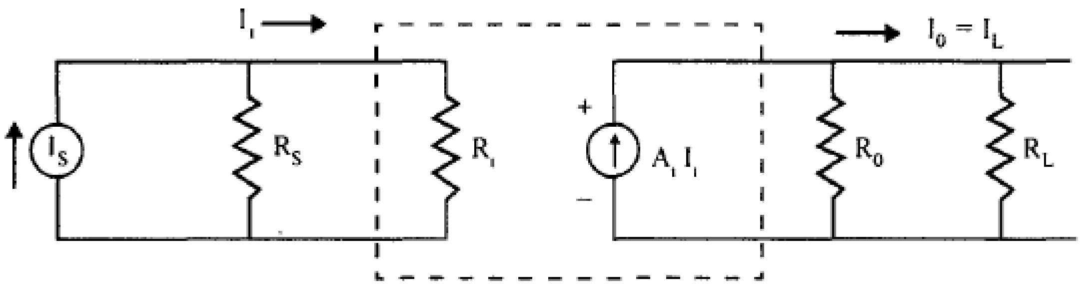
This circuit is a 2-port network and it represents an amplifier (see in Fig 7.1).
Suppose Ri» Rs, drop across Rs is very small.



Equivalent circuit of voltage amplifiers.

CURRENT AMPLIFIER

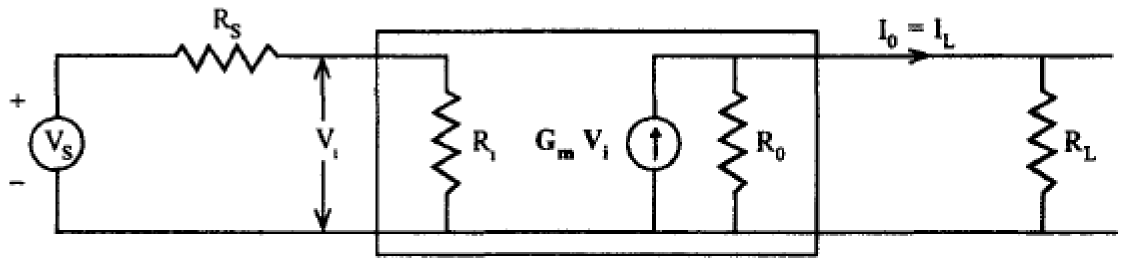
- An ideal current amplifier is one which gives output current proportional to input current and
- the proportionality factor is independent ofRs and RL.



TRANSCONDUCTANCE AMPLIFIER

Ideal Transconductance amplifier supplies output current which is proportional to input voltage

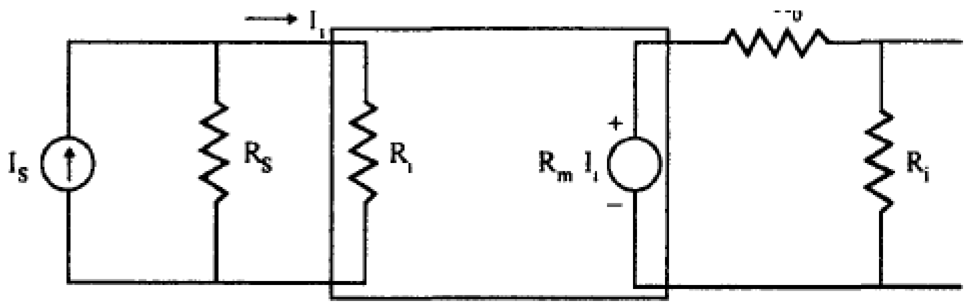
independently of the magnitude of Rs and RL.



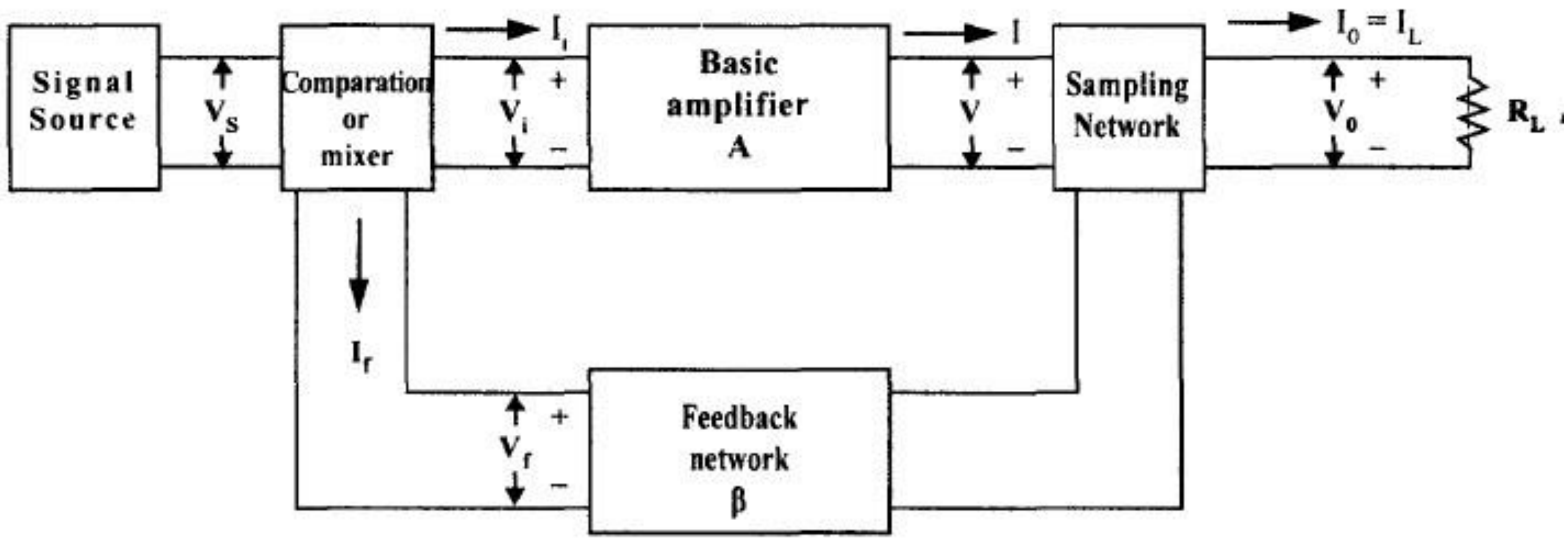
TRANS RESISTANCE AMPLIFIER

It gives output voltage Vo proportional to Is, independent of Rs a. RL. For *ideal amplifiers*

Rj =0, Ro=O



GENERALIZED BLOCK



Introduction To Feedback

- The process of injecting a fraction of output energy of some device back to the input is known as **feedback.**
- some of the short comings(drawbacks) of the amplifier circuit are:

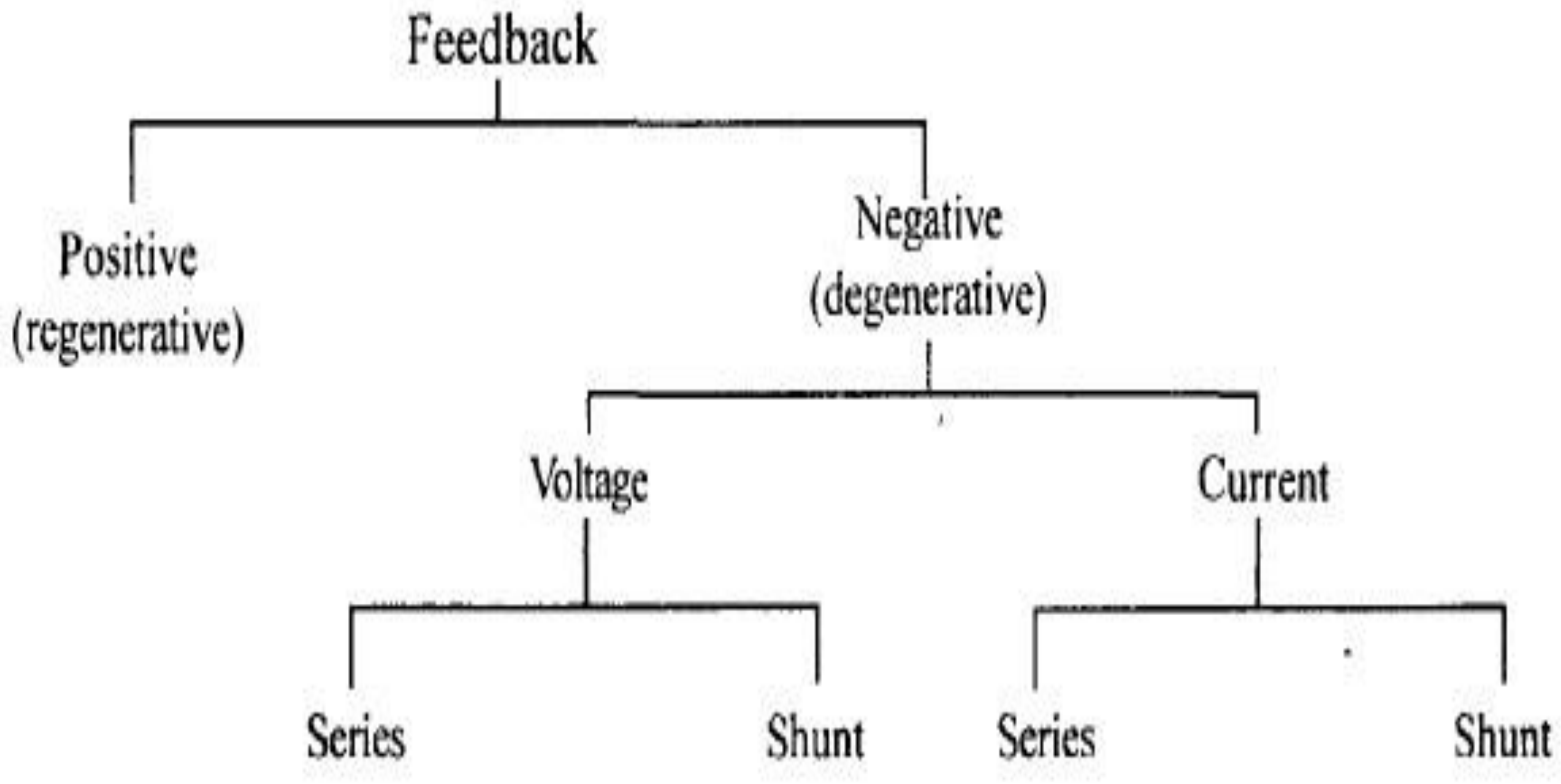
1.Change in the value of the gain due to variation in supplying voltage, temperature or due to components.

2.Distortion in wave-form due to non linearities in the operating characters of the amplifying device.

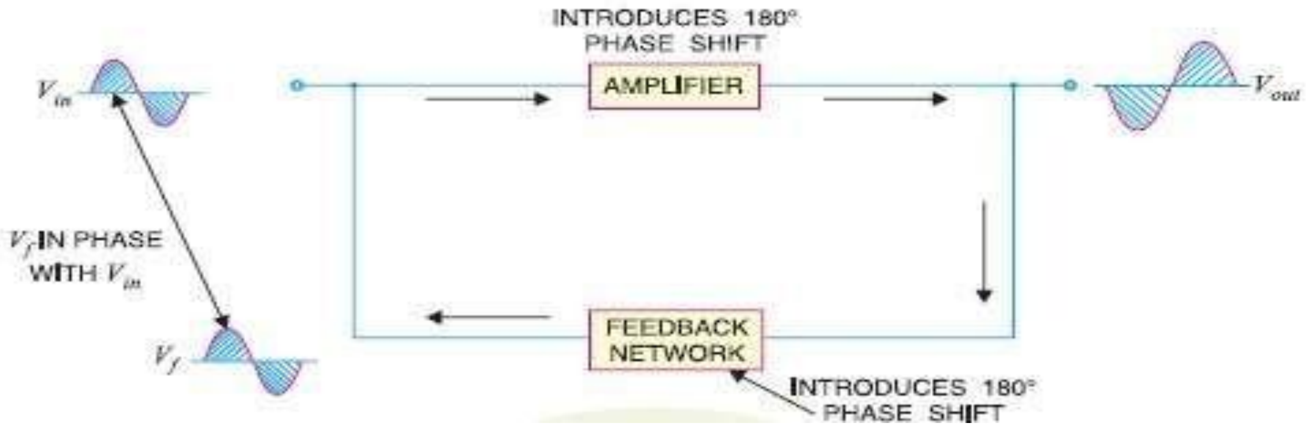
3.The amplifier may introduce noise (undesired signals)

- The above drawbacks can be minimizing if we introduce feedback

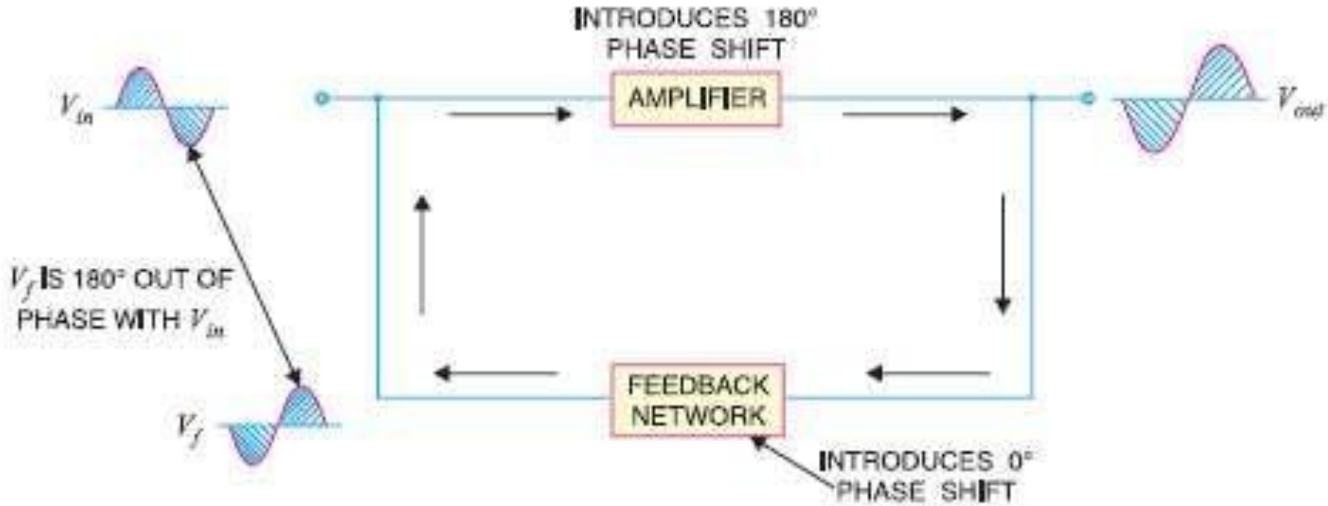
basic types of feedback in amplifiers



Positive feedback



Negative feedback.



CLASSIFACTION OF FEEDBACK AMPLIFIERS

voltage series feedback.

Voltage shunt Feedback

Current Shunt Feedback

Current Series Feedback

$$A_{Vf} = \frac{V_o}{V_s}$$

$$A_{If} = \frac{I_o}{I_s}$$

$$G_{Mf} = \frac{I_o}{V_s}$$

$$R_{Mf} = \frac{V_o}{I_s}$$

EFFECT OF NEGATIVE FEEDBACK ON TRANSFER GAIN

- REDUCTION IN GAIN

$$A'_V = \frac{A_v}{1+\beta A_v}$$ Denominator is > 1. $\therefore$ $A'_V < A_V$

- INCREASE IN BANDWIDTH

$$f_H' = f_H (1 + \beta_v A_{v\,(mid)})$$

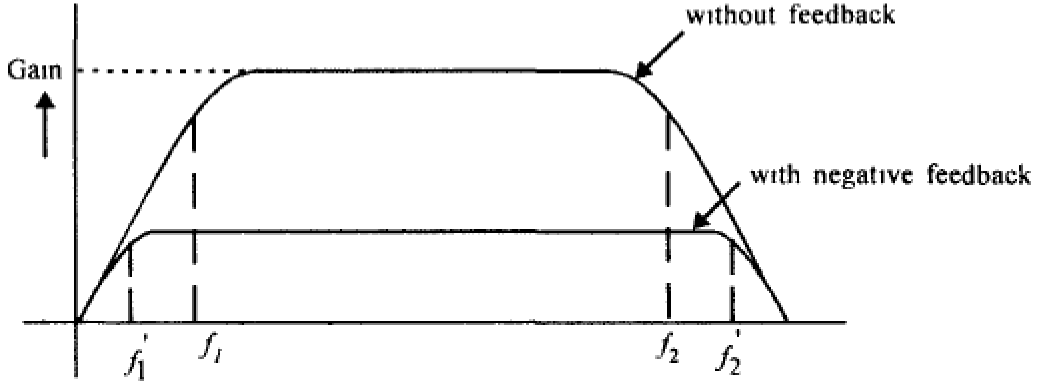
$$f_L' = \frac{f_L}{1 + \beta_v A_{v(mid)}}$$

- REDUCTION IN DISTORTION

$$\frac{D}{1 + \beta_v A_v} \text{ is} < D$$

- FEEDBACK TO IMPROVE SENSITIVITY
- FREQUENCY DISTORTION
- BAND WIDTH

$$(BW)_f = (1 + \beta A_m)\, BW$$



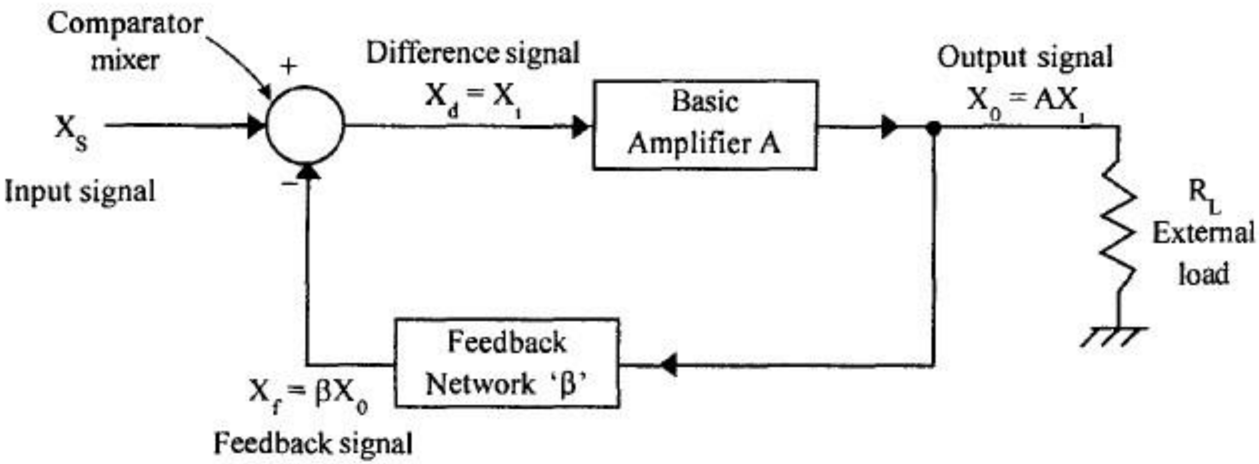
❖ REDUCTION OF NOISE

$$N_F = \frac{N}{1+\beta A}$$

$N_F < N$. Noise is reduced with negative feedback.

TRANSFER GAIN WITH FEEDBACK

Consider the generalized feedback amplifier



$$\boxed{A_f = \frac{A}{1+\beta A}}$$

A_f = gain with feedback.

A = transfer gain without feedback.

If $|A_f| < |A|$ the feedback is called as negative or degenerative, feedback

If $|A_f| > |A|$ the feedback is called as positive or regenerative, feedback

LOOP GAIN

Return Ratio

βA = Product of feedback factor β and amplification factor A is called as *Return Ratio.*

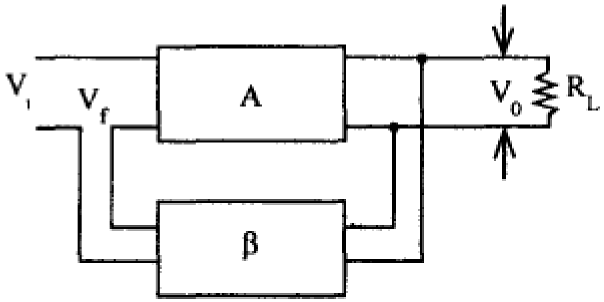
Return Difference (D)

The difference between unity (1) and return ratio is called as *Return difference.*

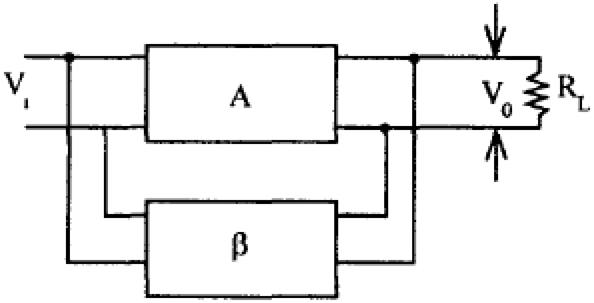
$$D = 1 - (-\beta A) = 1 + \beta A.$$

There are four types of feedback,

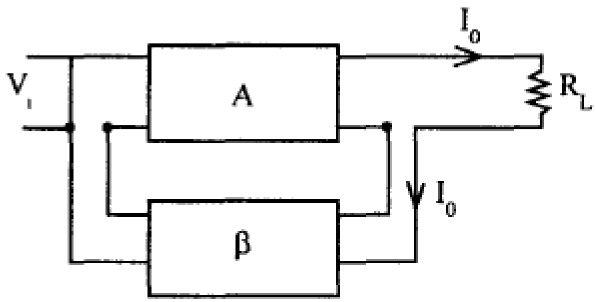
1. Voltage series feedback.
2. Voltage shunt feedback.
3. Current shunt feedback.
4. Current series feedback



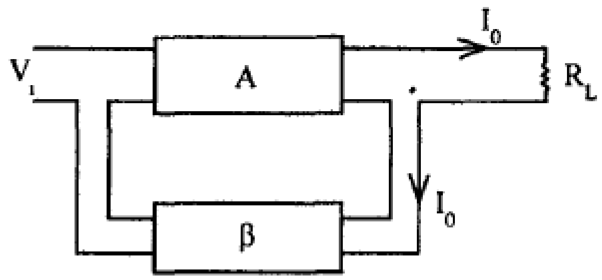
voltage series feedback.



Voltage shunt Feedback



Current Shunt Feedback



Current Series Feedback

EFFECT OF FEEDBACK ON INPUT RESISTANCE

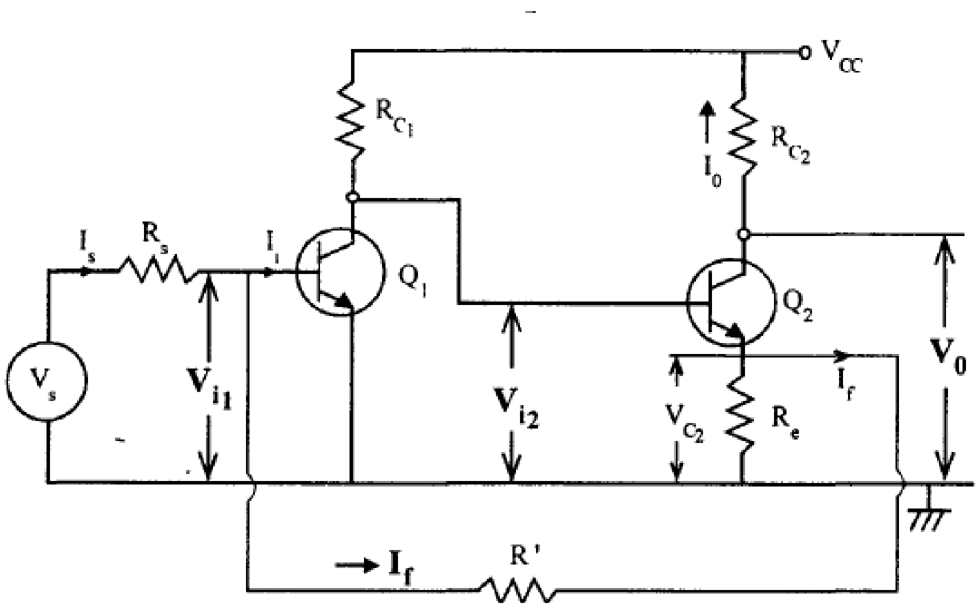
Voltage shunt Feedback

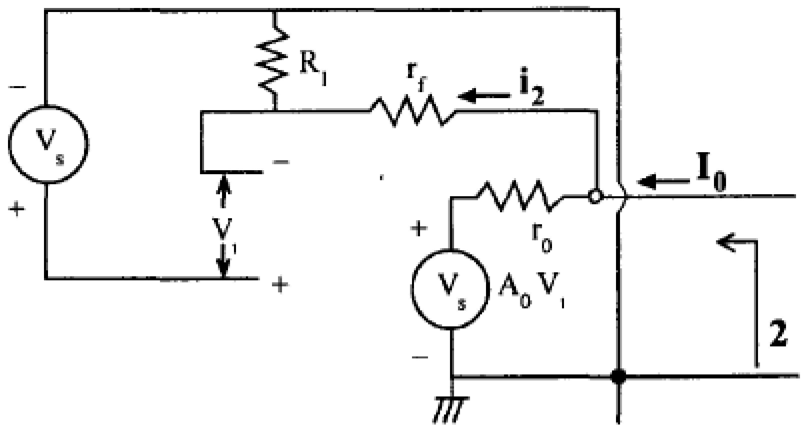
$$\boxed{R_i' = \frac{R_i}{(1+\beta_i A_i)}}$$

Current Shunt Feedback

$$\boxed{R_{if} = \frac{V_i}{(1+\beta A_I)I_i} = \frac{R_i}{1+\beta . A_I}}$$

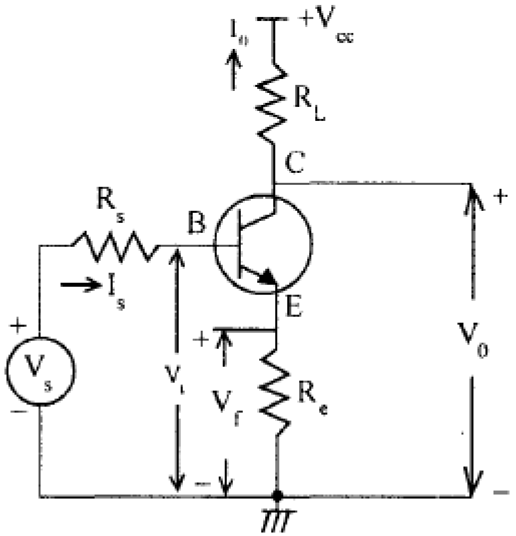
Current shunt feedback.



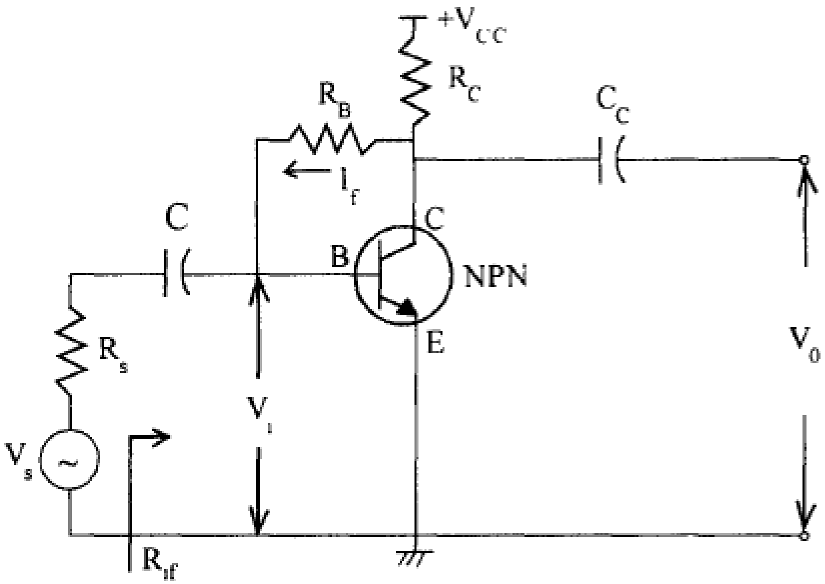


Equivalent circuit.

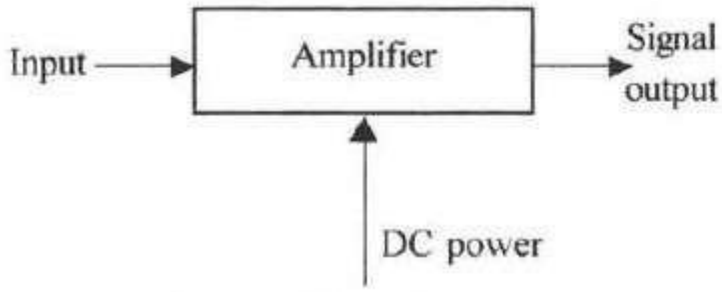
CURRENT SERIES FEEDBACK



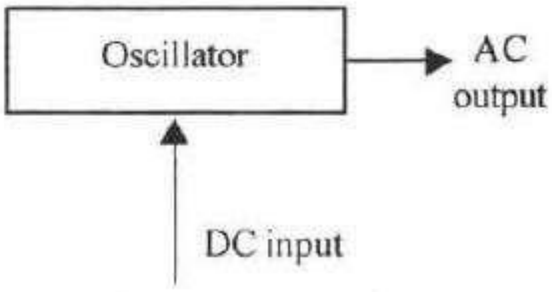
VOLTAGE SHUNT FEEDBACK



OSCILLATORS



(a) *Amplifier circuit*



(b) *Oscillator circuit*

Oscillator Circuit

- Oscillator is an electronic circuit which converts dc signal into ac signal.
- Oscillator is basically a positive feedback amplifier with unity loop gain.
- For an inverting amplifier- feedback network provides a phase shift of 180° while for non-inverting amplifier- feedback network provides a phase shift of 0° to get positive feedback .

$$\boxed{\frac{V_o}{V_s} = \frac{A}{1 - A\beta}}$$

If $\beta A=1$ then $V_o = \infty$; Very high output with zero input.

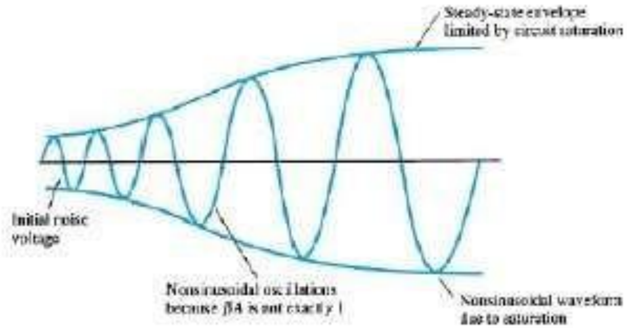
Use positive feedback through frequency-selective feedback network to ensure sustained oscillation at ω_0

Use of Oscillator Circuits

- Clock input for CPU, DSP chips …
- Local oscillator for radio receivers, mobile receivers, etc
- As a signal generators in the lab
- Clock input for analog-digital and digital-analog converters

Oscillators

- If the feedback signal is not positive and gain is less than unity, oscillations dampen out.
- If the gain is higher than unity then oscillation saturates.



Type of Oscillators

Oscillators can be categorized according to the types of feedback network used:

- RC Oscillators: Phase shift and Wien Bridge Oscillators
- LC Oscillators: Colpitt and Hartley Oscillators
- Crystal Oscillators

There are two types of oscillators circuits:

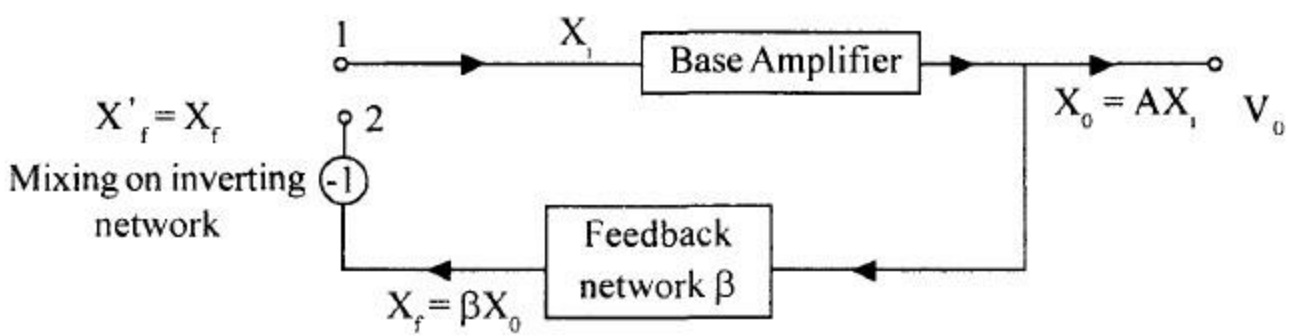
I. Harmonic Oscillators **2. Relaxation Oscillators**

PERFORMANCE MEASURES OF OSCILLATOR CIRCUITS:

- ***Stability:***
- ***Amplitude stability:***
- ***Output Power:***
- ***Harmonics:***

Total phase shift = 360^0 (180 + 180). Therefore, to get sustained oscillations,

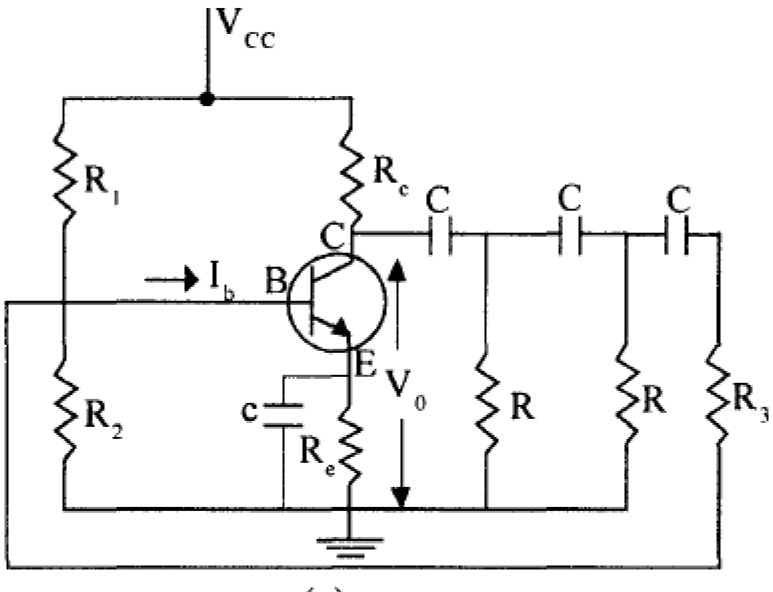
1. The loop gain must be unit 1.
2. Total Loop phase shift must be 0^0 or 360^0. (Amplifier circuit produces 180^0 phase shift and feedback network another 180^0.



BARKHAUSEN CRITERION

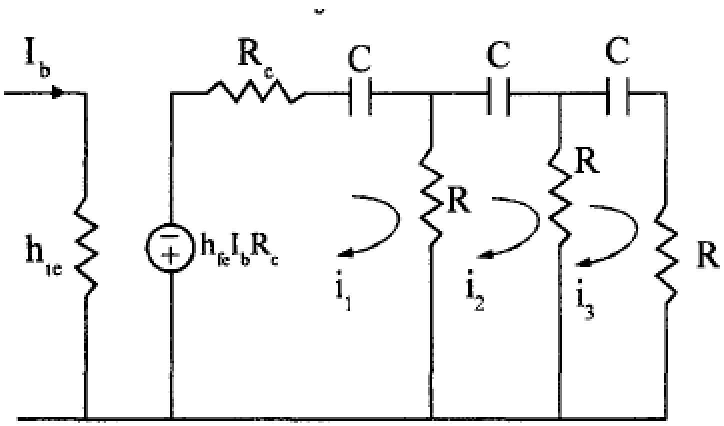
$|\beta A| = 1$ and phase of $-A\beta = 0$.

R - C PHASE-SHIFT OSCILLATOR



(a)

Transistor phase shift oscillator.



R - C Equivalent circuit.

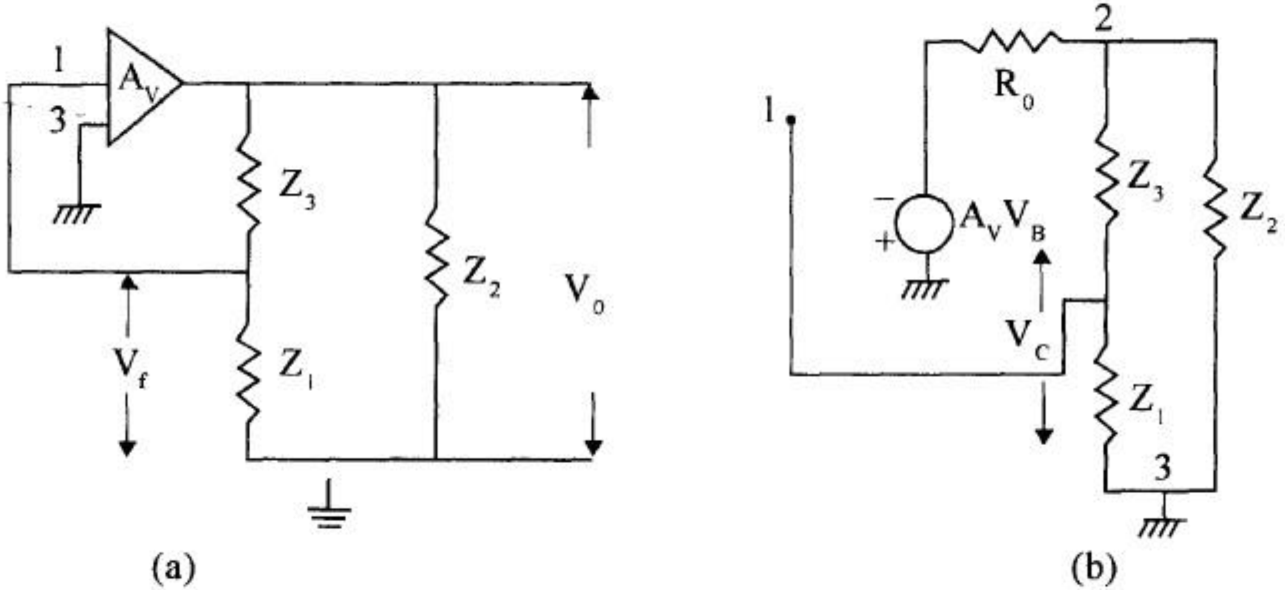
$$h_{fe}\,K > 4K^2 + 23K + 29$$

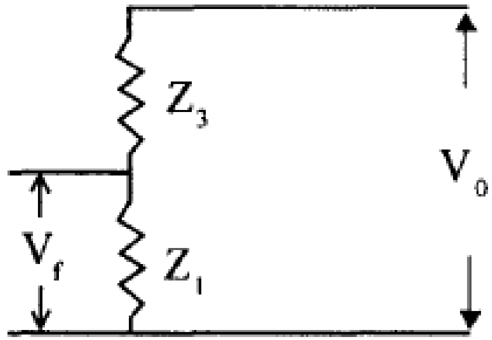
$$h_{fe} > 4K + 23 + \frac{29}{K}$$

K < 2.7

$$h_{fe} > 44.5$$

A GENERAL FORM OF LC OSCILLATOR CIRCUIT



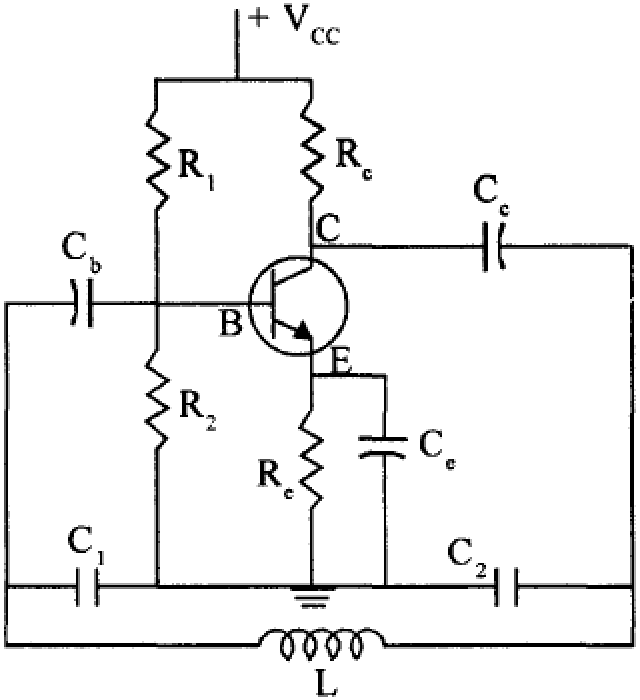


$$-A\beta = \frac{A_V X_1}{X_2}.$$

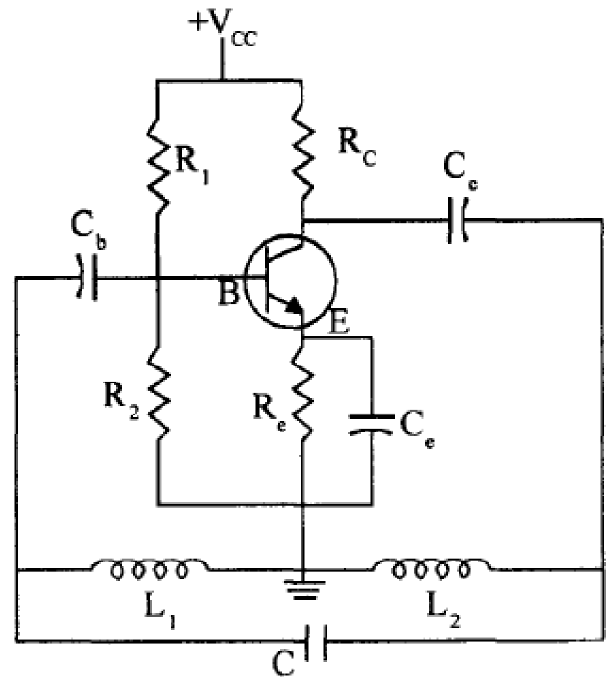
- Aβ must be positive, and at least unity in magnitude. Than XI and X2 must have the same sign.

$\boxed{\text{So if } X_1 \text{ and } X_2 \text{ are capacitive, } X_3 \text{ should be inductive and vice versa.}}$

If X_1 and X_2 are capacitors, the circuit is called ***Colpitts Oscillator***
If X_1 and X_2 are inductors, the circuit is called ***Hartely Oscillators***



(a) Colpitts oscillator



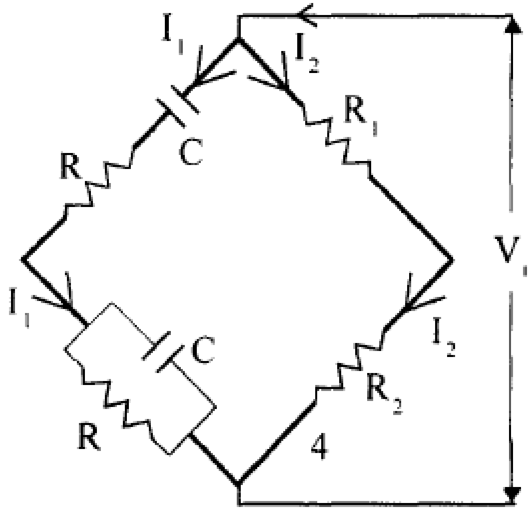
(b) Hartely oscillator circuit

$$\boxed{f = \frac{1}{2\pi\sqrt{L\,C_T}}}$$

where $C_T = \dfrac{C_1 C_2}{C_1 + C_2}$

$$\boxed{f = \frac{1}{2\pi\sqrt{(L_1 + L_2)\,C_3}}}$$

Wien bridge oscillator

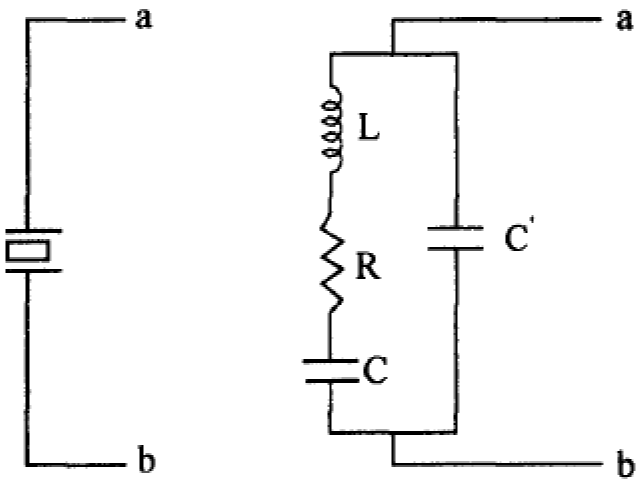


Wien Bridge oscillator circuit.

$$\boxed{f = \frac{1}{2\pi RC}}$$

$$\boxed{h_{fe} = 4k + 23 + \frac{29}{K}.}$$

CRYSTAL OSCILLATORS



Crystal *Electrical Model*

$$f = \frac{1}{2\pi}\sqrt{\frac{1}{LC} - \frac{R^2}{L^2}}$$

UNIT-V

LARGE SIGNAL AMPLIFIERS

Transistor Audio Power Amplifier

- A transistor amplifier which raises the power level of the signals that have audio frequency range is known as **transistor audio power amplifier.**
- A transistor that is suitable for power amplification is generally called a *power transistor*.
- The typical power output rating of a power amplifier is 1W or more.

Factors to be considered in large signal

- Output power
- Distortion Operating
- region Thermal
- considerations
- Efficiency (η)

Difference Between Voltage and Power

S. No.	Particular	Voltage amplifier	Power amplifier
1.	β	High (> 100)	low (5 to 20)
2.	R_C	High (4 – 10 kΩ)	low (5 to 20 Ω)
3.	*Coupling*	usually *R* – *C* coupling	Invariably transformer coupling
4.	*Input voltage*	low (a few mV)	High (2 – 4 V)
5.	*Collector current*	low (≃ 1 mA)	High (> 100 mA)
6.	*Power output*	low	high
7.	*Output impedance*	High (≃ 12 kΩ)	low (200 Ω)

Performance Quantities of Power Amplifiers

(i) Collector efficiency

The ratio of a.c. output power to the zero signal power (i.e. d.c. power) supplied by the battery of a power amplifier is known as **collector efficiency**.

(ii) Distortion

The change of output wave shape from the input wave shape of an amplifier is known as **distortion.**

(iii) Power dissipation capability

The ability of a power transistor to dissipate heat is known as **power dissipation capability.**

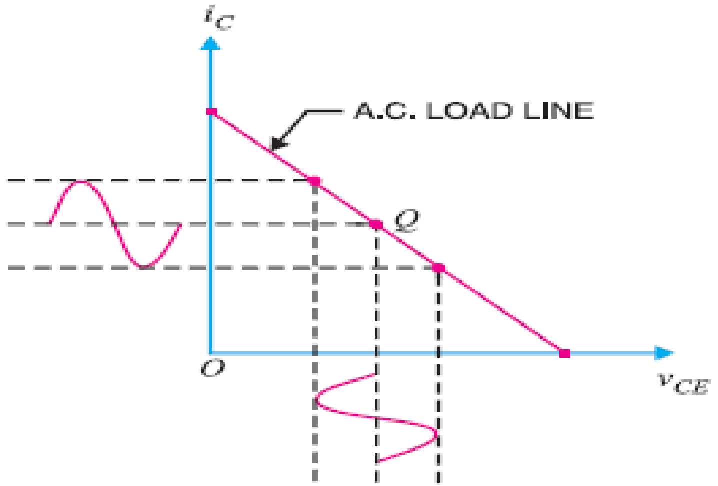
Classification of Power Amplifiers

- Class A: It is one, in which the active device conducts for the full 360°.
- Class B: Conduction for 180 °.
- Class C: Conduction for < 180°.
- Class AB :Conduction angle is between 180°. and 360°.
- Class D: These are used in *transmitters because their efficiency is high: 100%.*
- Class S:Switching regulators are based on class'S' operation.

Class A power amplifier

•If the collector current flows at all times during the full cycle of the signal, the power amplifier is known as **class A power amplifier.**

•If the Q point is placed near the centre a/the linear region a/the dynamic curve, class A operation results. Because the transistor will conduct for the complete 360 , distortion is low for small signals and conversion efficiency is low.



Types of class-A power Amplifiers

1. Series fed

There is no transformer in the circuit. RL is in series with V cc. There is DC power drop across RL. Therefore efficiency = 25% (maximum).

2. Transformer coupled

- The load is coupled through a transformer. DC drop across the primary of the transformer is

negligible. There is no DC drop across RL. Therefore efficiency = 50% maximum.

Series Fed class-A power Amplifier

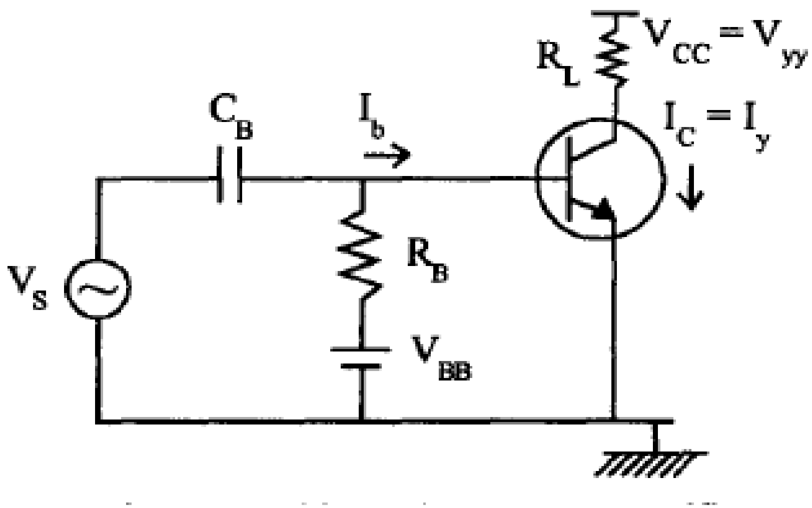


Fig.(a)Series fedClass A power amplifier circuit

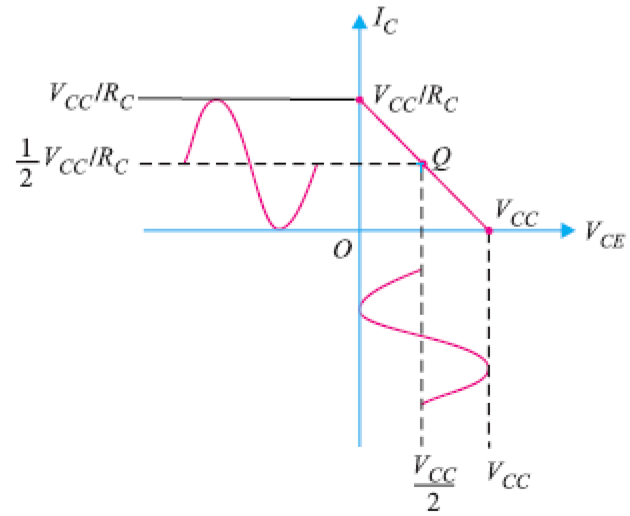


Fig.(b)Transter curve

Transformer Coupled class-A power Amplifier

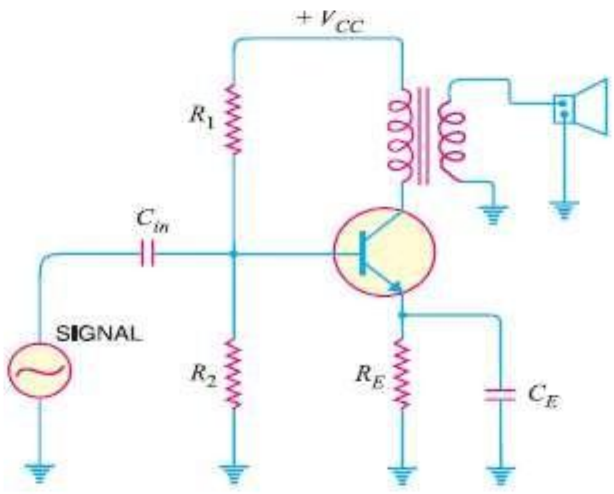


Fig.(a)Transformer Coupled Class A power amplifier circuit

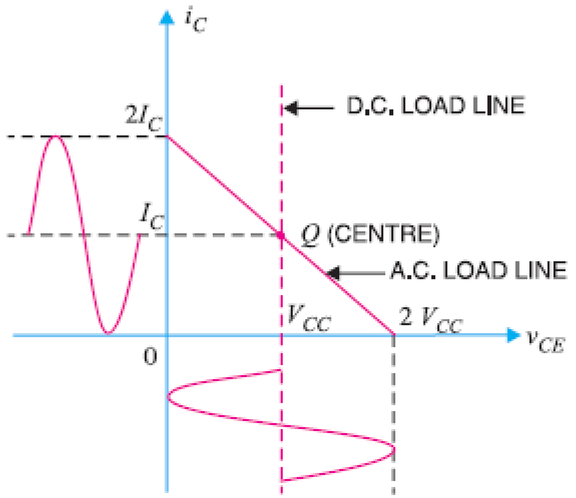
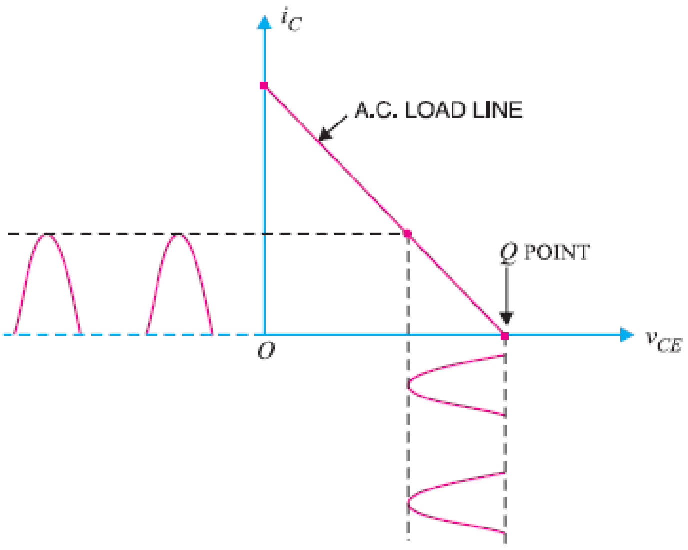


Fig.(b)Transfer curve

Class B power amplifier

- If the collector current flows only during the positive half-cycle of the input signal, it is called a **class B power amplifier**.

- For class B operation the Q point is set near cutoff. So output power will be more and conversion efficiency is more. Conduction is only for 180



Transfer curve

Types of class-B power Amplifiers

- **Push-Pull Amplifier**

The standard class B push-pull amplifier requires a centre tapped transformer

- **Complimentary Symmetry Circuits (Transformer Less Class B PowerAmplifier)**

Complementary symmetry circuits need only one phase

They don't require a centre tapped transformer.

Advantages & Disadvantages of Class B power Amplifier

Advantages

1.More output power; efficiency = 78.5%. Max.

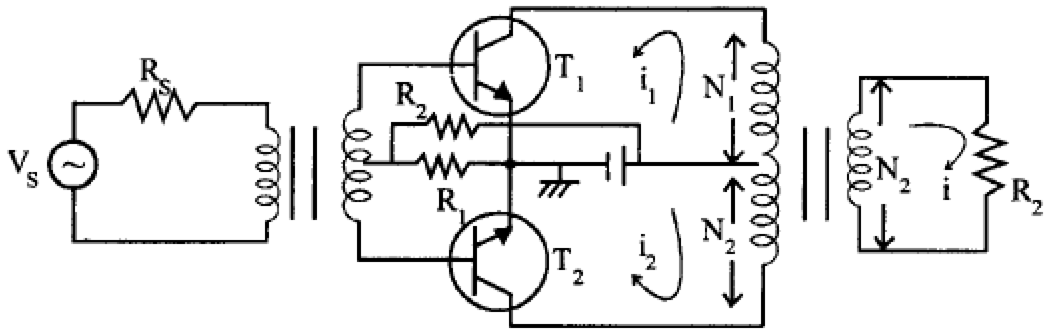
2.Efficiency is higher. Since the transistor conducts only for 180°, when it is not conducting, it will not draw DC current.

3.Negligible power loss at no signal. Disadvantages:

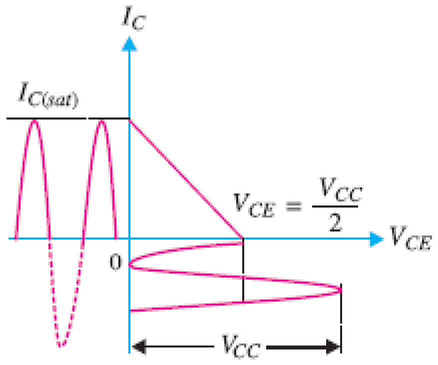
4.Supply voltage V cc should have good regulation. Since if V cc changes, the operating point changes (Since Ic changes). Therefore transistor may not be at cut off.

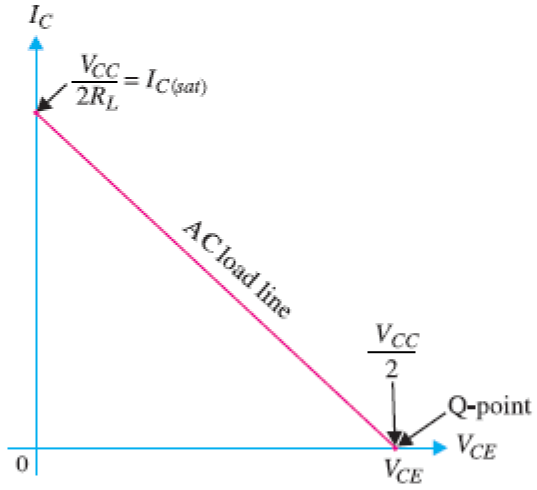
5.Harmonic distortion is higher. (This can be minimized by pushpull connection).

Class B Push-Pull Amplifier

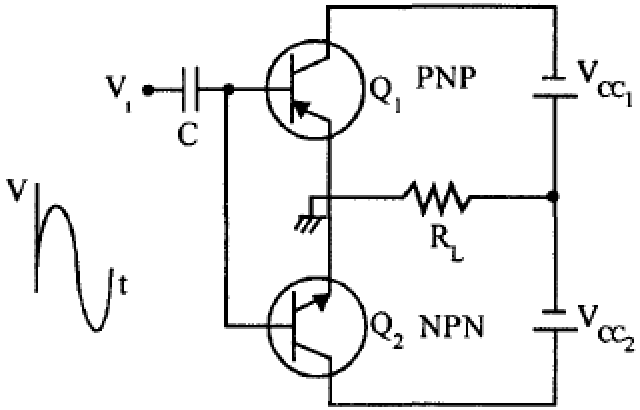


Push Pull amplifier circuit





Complimentary Symmetry Circuits (Transformer Less Class B Power Amplifier)



Differences between class-A & B power

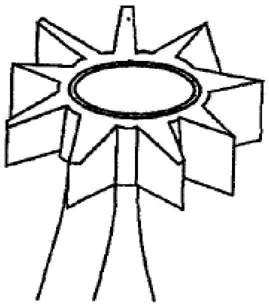
Class A	Class B
Less power Lesser η Less Harmonic distortion	More power More η upto 78.5% Harmonic distortion is more

Heat Sinks

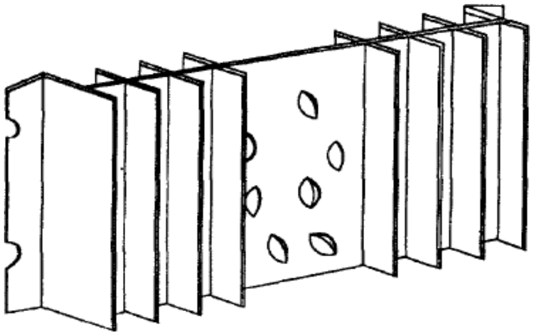
- The metal sheet that serves to dissipate the additional heat from the power transistor is known as **heat sink.**
- The purpose of heat sinks is to keep the operating temperature of the transistor low, to prevent thermal breakdown.
- Almost the entire heat in a transistor is produced at the collector-base junction. If the temperature exceeds the permissible limit, this junction is destroyed and the transistor is rendered useless.
- Most of power is dissipated at the collector-base junction. This is because collector-base voltage is much greater than the base-emitter voltage, although currents through the two junctions are almost the same.

High Power Transistor Type.

- re TO-3 and TO-66 types. These are diamond shaped. For power transistors, usually, the ease itself in the collector convention and radiation
- Finned aluminium heat sinks yield the best heat transfer per unit cost.



Fin-type heat sink



Power transistor heat sink